

HT32F59041 Datasheet

Enhanced 24-bit A/D Arm[®] Cortex[®]-M0+ Flash MCU 64 KB Flash and 8 KB SRAM with 1 MSPS 12-Bit ADC 24-Bit Delta Sigma ADC, DIV, USART, UART, SPI, I²C MCTM, GPTM, BFTM, PWM, CRC, RTC and WDT

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1 General Description

The Holtek HT32F59041 device is a high performance, low power consumption 32-bit microcontroller based around an Arm[®] Cortex[®]-M0+ processor core. The Cortex[®]-M0+ is a next-generation processor core which is tightly coupled with Nested Vectored Interrupt Controller (NVIC), SysTick timer, and including advanced debug support.

The device operates at a frequency of up to 20 MHz with a Flash accelerator to obtain maximum efficiency. It provides 64 KB of embedded Flash memory for code/data storage and 8 KB of embedded SRAM memory for system operation and application program usage. A variety of peripherals, such as Hardware Divider DIV, ADC, I²C, USART, UART, SPI, MCTM, GPTM, PWM, BFTM, CRC-16/32, RTC, WDT, SW-DP (Serial Wire Debug Port), etc., are also implemented in the device. Several power saving modes provide the flexibility for maximum optimization between wakeup latency and power consumption, an especially important consideration in low power applications.

The device also contains a multi-channel 24-bit Delta Sigma A/D converter which includes a programmable gain amplifier and is designed for applications that interface differentially to analog signals.

The above features ensure that the device is suitable for use in a wide range of applications, especially in areas such as white goods application controllers, power monitors, alarm systems, consumer products, handheld equipment, data logging applications, motor controllers and so on.

arm Cortex



2 Features

Core

- 32-bit Arm[®] Cortex[®]-M0+ processor core
- Up to 20 MHz operating frequency
- Single-cycle multiplication
- Integrated Nested Vectored Interrupt Controller (NVIC)
- 24-bit SysTick timer

The Cortex[®]-M0+ processor is a very low gate count, highly energy efficient processor that is intended for microcontroller and deeply embedded applications that require an area optimized, low-power processor. The processor is based on the ARMv6-M architecture and supports Thumb[®] instruction sets, single-cycle I/O port, hardware multiplier and low latency interrupt respond time.

On-chip Memory

- 64 KB on-chip Flash memory for instruction/data and options storage
- 8 KB on-chip SRAM
- Supports multiple boot modes

The Arm[®] Cortex[®]-M0+ processor accesses and debug accesses share the single external interface to external AHB peripherals. The processor accesses take priority over debug accesses. The maximum address range of the Cortex[®]-M0+ is 4 GB since it has a 32-bit bus address width. Additionally, a pre-defined memory map is provided by the Cortex[®]-M0+ processor to reduce the software complexity of repeated implementation by different device vendors. However, some regions are used by the Arm[®] Cortex[®]-M0+ system peripherals. Refer to the Arm[®] Cortex[®]-M0+ Technical Reference Manual for more information. Figure 2 in the Overview chapter shows the memory map of the device, including code, SRAM, peripheral and other pre-defined regions.

Flash Memory Controller – FMC

- 32-bit word programming with In System Programming Interface (ISP) and In Application Programming (IAP)
- Flash protection capability to prevent illegal access

The Flash Memory Controller, FMC, provides all the necessary functions for the embedded onchip Flash Memory. The word program/page erase functions are also provided.



Reset Control Unit – RSTCU

- Supply supervisor:
 - Power on Reset / Power down Reset POR / PDR
 - Brown-out Detector BOD
 - Programmable Low Voltage Detector LVD

The Reset Control Unit, RSTCU, has three kinds of reset, a power on reset, a system reset and an APB unit reset. The power on reset, known as a cold reset, resets the full system during power up. A system reset resets the processor core and peripheral IP components with the exception of the SW-DP controller. The resets can be triggered by external signals, internal events and the reset generators.

Clock Control Unit – CKCU

- External 4 to 20 MHz crystal oscillator
- External 32.768 kHz crystal oscillator
- Internal 20 MHz RC oscillator trimmed to ±2 % accuracy at 25 °C operating temperature
- Internal 32 kHz RC oscillator
- Independent clock divider and gating bits for peripheral clock sources

The Clock Control Unit, CKCU, provides a range of oscillator and clock functions. These include a High Speed Internal RC oscillator (HSI), a High Speed External crystal oscillator (HSE), a Low Speed Internal RC oscillator (LSI), a Low Speed External crystal oscillator (LSE), an HSE clock monitor, clock pre-scalers, clock multiplexers, APB clock divider and gating circuitry. The AHB, APB and Cortex[®]-M0+ clocks are derived from the system clock (CK_SYS) which can come from the HSI, HSE, LSI or LSE. The Watchdog Timer and Real Time Clock (RTC) use either the LSI or LSE as their clock source.

Power Management Control Unit – PWRCU

- Single V_{DD} power supply: 2.5 V to 5.5 V
- Integrated 1.5 V LDO regulator for CPU core, peripherals and memories power supply
- Two power domains: V_{DD} and 1.5 V
- Three power saving modes: Sleep, Deep-Sleep1, Deep-Sleep2

Power consumption can be regarded as one of the most important issues for many embedded system applications. Accordingly the Power Control Unit, PWRCU, in the device provides many types of power saving modes such as Sleep, Deep-Sleep1 and Deep-Sleep2 mode. These operating modes reduce the power consumption and allow the application to achieve the best trade-off between the conflicting demands of CPU operating time, speed and power consumption.



2 Features

Real Time Clock – RTC

- 24-bit up-counter with a programmable prescaler
- Alarm function
- Interrupt and Wake-up event

The Real Time Clock, RTC, includes an APB interface, a 24-bit count-up counter, a control register, a prescaler, a compare register and a status register. The RTC circuits are located in the V_{DD15} power domain. The RTC counter is used as a wakeup timer to generate a system resume or interrupt signal from the MCU power saving mode.

External Interrupt / Event Controller – EXTI

- Up to 16 EXTI lines with configurable trigger source and type
- All GPIO pins can be selected as EXTI trigger source
- Source trigger type includes high level, low level, negative edge, positive edge, or both edges
- Individual interrupt enable, wakeup enable and status bits for each EXTI line
- Software interrupt trigger mode for each EXTI line
- Integrated deglitch filter for short pulse blocking

The External Interrupt/Event Controller, EXTI, comprises 16 edge detectors which can generate a wake-up event or interrupt requests independently. Each EXTI line can also be masked independently.

Hardware Divider – DIV

- Signed/unsigned 32-bit divider
- Operation in 8 clock cycles, load in 1 clock cycle
- Divide by zero error Flag

The divider is the truncated division and needs a software triggered start signal by using the control register "START" bit. After 8 clock cycles, the divider calculate complete flag will be set to 1, and if the divisor register data is zero, the divide by zero error flag will be set to 1.

12-Bit Analog to Digital Converter – ADC

- 12-bit SAR ADC engine
- Up to 1 Msps conversion rate
- Up to 12 external analog input channels

A 12-bit multi-channel ADC is integrated in the device. There are multiplexed channels, which include 12 external analog signal channels and 2 internal channels which can be measured. If the input voltage is required to remain within a specific threshold window, an Analog Watchdog function will monitor and detect these signals. An interrupt will then be generated to inform the device that the input voltage is not within the preset threshold levels. There are three conversion modes to convert an analog signal to digital data. The ADC can be operated in one shot, continuous and discontinuous conversion modes.



24-Bit Delta Sigma Analog to Digital Converter – $\Delta\Sigma$ ADC

- Internal Programmable Gain Amplifier
- Internal I²C interface for external communication
- $\blacksquare 5 \text{ Hz} \sim 1.6 \text{ kHz ADC} \text{ output data rate}$
- Internal temperature sensor for compensation

I/O Ports – GPIO

- 30 GPIOs
- Port A, B, C are mapped as 16 external interrupts EXTI
- Almost all I/O pins have configurable output driving current

There are 30 General Purpose I/O pins, GPIO, for the implementation of logic input/output functions. Each of the GPIO ports has a series of related control and configuration registers to maximize flexibility and to meet the requirements of a wide range of applications.

The GPIO ports are pin-shared with other alternative functions to obtain maximum functional flexibility on the package pins. The GPIO pins can be used as alternative functional pins by configuring the corresponding registers regardless of the input or output pins. The external interrupts on the GPIO pins of the device have related control and configuration registers in the External Interrupt Control Unit, EXTI.

Basic Function Timer – BFTM

- One 32-bit compare match count-up counter no I/O control features
- One shot mode counting stops after compare match occurs
- Repetitive mode restart counter when compare match occurs

The Basic Function Timer is a simple 32-bit up-counting counter designed to measure time intervals and generate a one shot or repetitive interrupts. The BFTM operates in two functional modes, repetitive and one shot modes. In the repetitive mode, the BFTM restarts the counter when a compare match event occurs. The BFTM also supports a one shot mode which forces the counter to stop counting when a compare match event occurs.

Motor Control Timer – MCTM

- One 16-bit up, down, up/down auto-reload counter
- 16-bit programmable prescaler allowing counter clock frequency divided by any factor between 1 and 65536
- Input Capture function
- Compare Match Output
- PWM waveform generation with Edge-aligned and Center-aligned Counting Modes
- Single Pulse Mode Output
- Complementary Outputs with programmable dead-time insertion
- Break input to force the timer's output signals into a reset or fixed condition

Features



The Motor Control Timer consists of one 16-bit up/down-counter, four 16-bit Capture/Compare Registers (CCRs), one 16-bit Counter Reload Register (CRR), one 8-bit repetition counter and several control/status registers. It can be used for a variety of purposes including measuring the pulse width of input signals or generating output waveforms such as compare match outputs, PWM outputs or complementary PWM outputs with dead-time insertion. The MCTM is capable of offering full functional support for motor control, hall sensor interfacing and break input.

PWM Generation and Capture Timer – GPTM

- One 16-bit up, down, up/down auto-reload counter
- Up to 4 independent channels for each timer
- 16-bit programmable prescaler allowing the counter clock frequency devided by any factor between 1 and 65536
- Input Capture function
- Compare Match Output
- PWM waveform generation with Edge-aligned and Center-aligned Counting Modes
- Single Pulse Mode Output
- Encoder interface controller with two inputs using quadrature decoder

The General Purpose Timer consists of one 16-bit up/down-counter, four 16-bit Capture/Compare Registers (CCRs), one 16-bit Counter Reload Register (CRR) and several control/status registers. They can be used for a variety of purposes including general time measurement, input signal pulse width measurement, output waveform generation such as single pulse generation or PWM output generation. The GPTM supports an Encoder Interface using a decoder with two inputs.

Pulse Width Modulation – PWM

- One 16-bit up, down, up/down auto-reload counter
- Up to 4 independent channels for each timer
- 16-bit programmable prescaler allowing counter clock frequency divided by any factor between 1 and 65536
- Compare Match Output
- PWM waveform generation with Edge-aligned and Center-aligned Counting Modes
- Single Pulse Mode Output

The Pulse Width Modulator consists of one 16-bit up/down-counter, four 16-bit Compare Registers (CRs), one 16-bit Counter-Reload Register (CRR) and several control/status registers. It can be used for a variety of purposes including general timer and output waveform generation such as single pulse generation or PWM output.



Watchdog Timer – WDT

- 12-bit down counter with 3-bit prescaler
- Reset event for the system
- Programmable watchdog timer window function
- Register write protection function

The Watchdog Timer is a hardware timing circuit that can be used to detect system failures due to software malfunctions. It includes a 12-bit count-down counter, a prescaler, a WDT delta value register, WDT operation control circuitry and a WDT protection mechanism. If the software does not reload the counter value before a Watchdog Timer underflow occurs, a reset will be generated when the counter underflows. In addition, a reset is also generated if the software reloads the counter when the counter value is greater than the WDT delta value. This means the counter must be reloaded within a limited timing window using a specific method. The Watchdog Timer counter can be stopped while the processor is in the debug mode. There is a register write protect function which can be enabled to prevent it from changing the Watchdog Timer configuration unexpectedly.

Inter-integrated Circuit – I²C

- Supports both master and slave modes with a frequency of up to 1 MHz
- Provides an arbitration function and clock synchronization
- Supports 7-bit and 10-bit addressing modes and general call addressing
- Supports slave multi-addressing mode with address mask function

The I²C is an internal circuit allowing communication with an external I²C interface which is an industry standard two line serial interface used for connection to external hardware. These two serial lines are known as a serial data line, SDA, and a serial clock line, SCL. The I²C module provides three data transfer rates: 100 kHz in the Standard mode, 400 kHz in the Fast mode and 1 MHz in the Fast plus mode. The SCL period generation register is used to setup different kinds of duty cycle implementations for the SCL pulse.

The SDA line which is connected directly to the I²C bus is a bi-directional data line between the master and slave devices and is used for data transmission and reception. The I²C also has an arbitration detect function and clock synchronization to prevent situations where more than one master attempts to transmit data to the I²C bus at the same time.

Serial Peripheral Interface – SPI

- Supports both master and slave modes
- Frequency of up to $(f_{PCLK}/2)$ MHz for the master mode and $(f_{PCLK}/3)$ MHz for the slave mode
- FIFO Depth: 8 levels
- Multi-master and multi-slave operation

The Serial Peripheral Interface, SPI, provides an SPI protocol data transmit and receive function in both master and slave modes. The SPI interface uses 4 pins, which are the serial data input and output lines MISO and MOSI, the clock line, SCK, and the slave select line, SEL. One SPI device acts as a master device which controls the data flow using the SEL and SCK signals to indicate the start of data communication and the data sampling rate. To receive a data byte, the streamed data



bits are latched on a specific clock edge and stored in the data register or in the RX FIFO. Data transmission is carried out in a similar way but in a reverse sequence. The mode fault detection provides a capability for multi-master applications.

Universal Synchronous Asynchronous Receiver Transmitter – USART

- Supports both asynchronous and clocked synchronous serial communication modes
- Asynchronous operating baud-rate clock frequency up to (f_{PCLK}/16) MHz and synchronous operating clock frequency up to (f_{PCLK}/8) MHz
- Full duplex communication
- Fully programmable serial communication characteristics including:
 - Word length: 7, 8 or 9-bit character
 - Parity: Even, odd or no-parity bit generation and detection
 - Stop bit: 1 or 2 stop bit generation
 - Bit order: LSB-first or MSB-first transfer
- Error detection: Parity, overrun and frame error
- Auto hardware flow control mode RTS, CTS
- IrDA SIR encoder and decoder
- RS485 mode with output enable control
- FIFO Depth: 8×9 bits for both receiver and transmitter

The Universal Synchronous Asynchronous Receiver Transceiver, USART, provides a flexible full duplex data exchange using synchronous or asynchronous transfer. The USART is used to translate data between parallel and serial interfaces, and is commonly used for RS232 standard communication. The USART peripheral function supports four types of interrupt including Line Status Interrupt, Transmitter FIFO Empty Interrupt, Receiver Threshold Level Reaching Interrupt and Time Out Interrupt. The USART module includes a transmitter FIFO (TX FIFO) and receiver FIFO (RX FIFO). The software can detect a USART error status by reading the Line Status Register, LSR. The status includes the type and the condition of transfer operations as well as several error conditions resulting from Parity, Overrun, Framing and Break events.

Universal Asynchronous Receiver Transmitter – UART

- Asynchronous serial communication operating baud-rate clock frequency up to (f_{PCLK}/16) MHz
- Full duplex communication
- Fully programmable serial communication characteristics including:
 - Word length: 7, 8 or 9-bit character
 - Parity: Even, odd or no-parity bit generation and detection
 - Stop bit: 1 or 2 stop bit generation
 - Bit order: LSB-first or MSB-first transfer
- Error detection: Parity, overrun and frame error

The Universal Asynchronous Receiver Transceiver, UART, provides a flexible full duplex data exchange using asynchronous transfer. The UART is used to translate data between parallel and serial interfaces, and is commonly used for RS232 standard communication. The UART peripheral function supports Line Status Interrupt. The software can detect a UART error status by reading



the Line Status Register, LSR. The status includes the type and the condition of transfer operations as well as several error conditions resulting from Parity, Overrun, Framing and Break events.

Cyclic Redundancy Check – CRC

- Support CRC16 polynomial: 0x8005, X¹⁶ + X¹⁵ + X² + 1
- Support CCITT CRC16 polynomial: 0x1021, $X^{16} + X^{12} + X^5 + 1$
- Support IEEE-802.3 CRC32 polynomial: 0x04C11DB7, X³² + X²⁶ + X²³ + X²² + X¹⁶ + X¹² + X¹¹ + X¹⁰ + X⁸ + X⁷ + X⁵ + X⁴ + X² + X + 1
- Supports 1's complement, byte reverse & bit reverse operation on data and checksum
- Supports byte, half-word & word data size
- Programmable CRC initial seed value
- CRC computation executed in 1 AHB clock cycle for 8-bit data and 4 AHB clock cycles for 32bit data

The CRC calculation unit is an error detection technique test algorithm which is used to verify data transmission or storage data correctness. A CRC calculation takes a data stream or a block of data as its input and generates a 16-bit or 32-bit output remainder. Ordinarily, a data stream is suffixed by a CRC code and used as a checksum when being sent or stored. Therefore, the received or restored data stream is calculated by the same generator polynomial as described above. If the new CRC code result does not match the one calculated earlier, that means the data stream contains a data error.

Debug Support

- Serial Wire Debug Port SW-DP
- 4 comparators for hardware breakpoint or code / literal patch
- 2 comparators for hardware watch points

Package and Operation Temperature

- 48-pin LQFP package
- Operation temperature range: -40 °C to + 85 °C



3 Overview

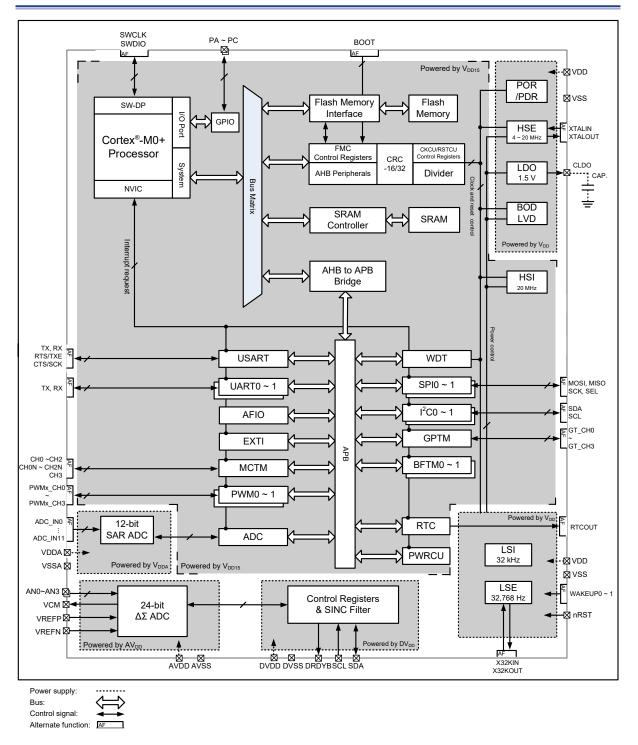
Device Information

Periph	nerals				
		HT32F59041			
Main Flash (KB)		63			
Option Bytes Flash (KB)		1			
SRAM (KB)		8			
	МСТМ	1			
	GPTM	1			
Timers	PWM	2			
TITIEIS	BFTM	2			
	WDT	1			
	RTC	1			
	SPI	2			
Communication	USART	1			
Communication	UART	2			
	I ² C	2			
Hardware Divider		1			
CRC-16/32		1			
EXTI		16			
12-bit ADC		1			
Number of channels		12 Channels			
24-bit ADC		1			
Number of channels		4 Channels			
GPIO		30			
CPU frequency		Up to 20 MHz			
Operating voltage		2.5 V ~ 5.5 V			
Operating temperature		-40 °C ~ 85 °C			
Package		48-pin LQFP			

Note: The detailed functions listed here, except the 24-bit Delta Sigma A/D Converter, are compatible with the HT32F50241 device. Refer to the HT32F50241 user manual for detailed function descriptions.



Block Diagram







Memory Map

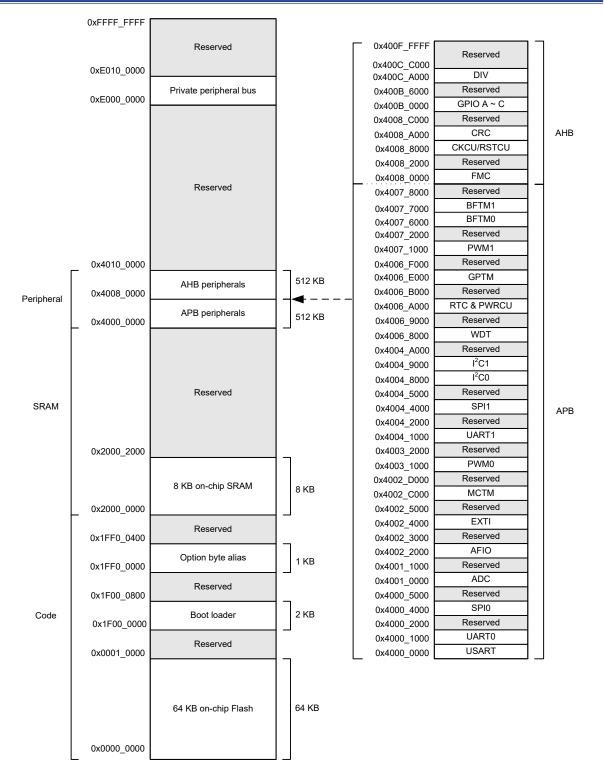


Figure 2. Memory Map

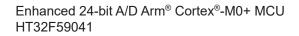




Table 2. Register Map

Start Address	End Address	Peripheral	Bus
0x4000_0000	0x4000_0FFF	USART	
0x4000_1000	0x4000_1FFF	UART0	
0x4000_2000	0x4000_3FFF	Reserved	
0x4000_4000	0x4000_4FFF	SPI0	
0x4000_5000	0x4000_FFFF	Reserved	
0x4001_0000	0x4001_0FFF	ADC	
0x4001_1000	0x4002_1FFF	Reserved	
0x4002_2000	0x4002_2FFF	AFIO	
0x4002_3000	0x4002_3FFF	Reserved	
0x4002_4000	0x4002_4FFF	EXTI	
0x4002_5000	0x4002_BFFF	Reserved	
0x4002_C000	0x4002_CFFF	MCTM	
0x4002_D000	0x4003_0FFF	Reserved	
0x4003_1000	0x4003_1FFF	PWM0	
0x4003_2000	0x4004_0FFF	Reserved	
0x4004_1000	0x4004_1FFF	UART1	
0x4004_2000	0x4004_3FFF	Reserved	APB
0x4004_4000	0x4004_4FFF	SPI1	
0x4004_5000	0x4004_7FFF	Reserved	
0x4004_8000	0x4004_8FFF	I ² C0	
0x4004_9000	0x4004_9FFF	I ² C1	
0x4004_A000	0x4006_7FFF	Reserved	
0x4006_8000	0x4006_8FFF	WDT	
0x4006_9000	0x4006_9FFF	Reserved	
0x4006_A000	0x4006_AFFF	RTC & PWRCU	
0x4006_B000	0x4006_DFFF	Reserved	
0x4006_E000	0x4006_EFFF	GPTM	
0x4006_F000	0x4007_0FFF	Reserved	
0x4007_1000	0x4007_1FFF	PWM1	
0x4007_2000	0x4007_5FFF	Reserved	
0x4007_6000	0x4007_6FFF	BFTM0	
0x4007_7000	0x4007_7FFF	BFTM1	
0x4007_8000	0x4007_FFFF	Reserved	



Start Address	End Address	Peripheral	Bus
0x4008_0000	0x4008_1FFF	FMC	
0x4008_2000	0x4008_7FFF	Reserved	
0x4008_8000	0x4008_9FFF	CKCU/RSTCU	
0x4008_A000	0x4008_BFFF	CRC	
0x4008_C000	0x400A_FFFF	Reserved	
0x400B_0000	0x400B_1FFF	GPIOA	AHB
0x400B_2000	0x400B_3FFF	GPIOB	
0x400B_4000	0x400B_5FFF	GPIOC	
0x400B_6000	0x400C_9FFF	Reserved	
0x400C_A000	0x400C_BFFF	DIV	
0x400C_C000	0x400F_FFFF	Reserved	



Clock Structure

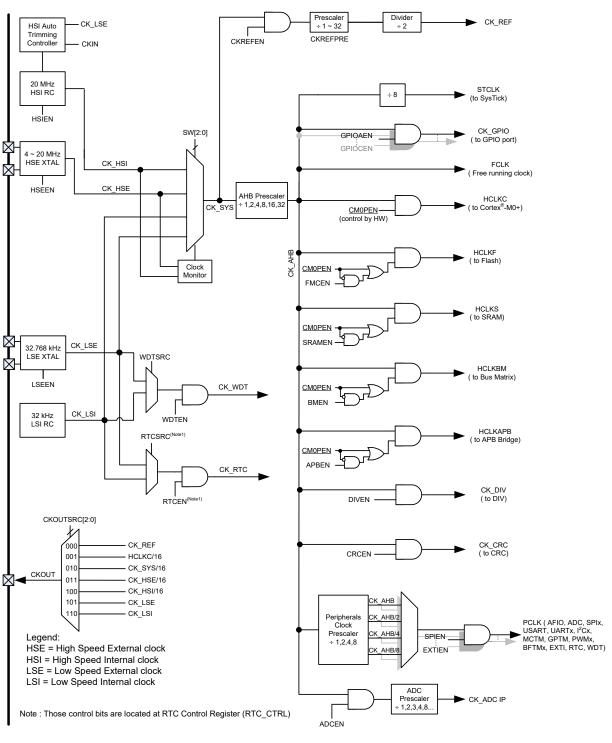


Figure 3. Clock Structure



4 24-Bit Delta Sigma A/D Converter – ΔΣ ADC

The device contains a high accuracy multi-channel 24-bit Delta Sigma type analog-to-digital converter which can directly interface to external analog signals, such as that from sensors or other control signals and convert these signals directly into a 24-bit digital value. In addition to the core analog to digital converter circuitry, the A/D converter module also includes an internal Programmable Gain Amplifier PGA. The PGA gain control, ADC gain control and ADC reference gain control determine the overall amplification gain for ADC input signal, giving users a flexible way of setting up an overall gain to achieve an optimum amplification of the input signal for their specific applications. The converter has a total of four inputs allowing the formation of two differential input channels. The converter output is filtered via a SINC filter and the result stored as a 24-bit value in three data registers. An internal voltage regulator and reference sources are also included as well as a temperature sensor for A/D converter compensation due to temperature effects.

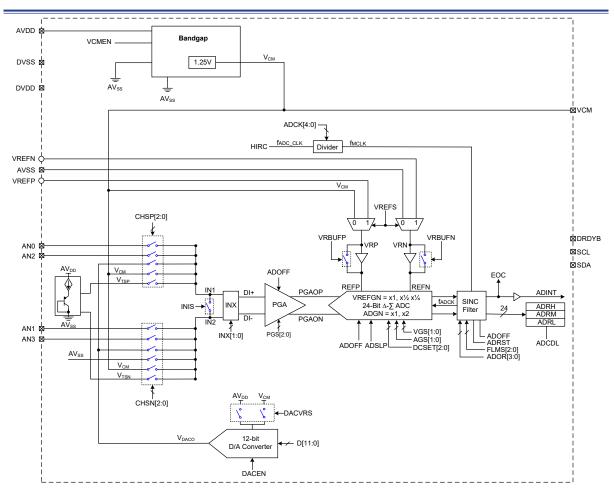


Figure 4. 24-bit A/D Converter Block Diagram



24-Bit A/D Converter Internal Registers

The 24-bit A/D converter is setup and operated using a series of internal registers. Device commands and data are written to and read from the 24-bit ADC module using its internal I^2C bus. This list provides a summary of all the 24-bit ADC module internal registers, their detailed operation is described under their relevant section in the functional description.

Register Initial Values

The following table shows the internal value of the individual register after a power on reset.

0 1
Power On Reset Value
0000 0000
-000 0000
-000 000-
00 0000
XXXX XXXX
XXXX XXXX
XXXX XXXX
0010 0000
0000 000-
0 0000
1110 0100
0000 0000
0000
00
0 00
0000 0000
001

Table Legend

Item	Description
*	Warm reset
-	Not implemented
u	Unchanged
x	Unknown

Address	Register Bit								
Audress	Name	7	6	5	4	3	2	1	0
00H	PWRC	VCMEN	D6	D5	D4	D3	D2	D1	D0
01H	PGAC0	—	VGS1	VGS0	AGS1	AGS0	PGS2	PGS1	PGS0
02H	PGAC1	—	INIS	INX1	INX0	DCSET2	DCSET1	DCSET0	—
03H	PGACS			CHSN2	CHSN1	CHSN0	CHSP2	CHSP1	CHSP0
04H	ADRL	D7	D6	D5	D4	D3	D2	D1	D0
05H	ADRM	D15	D14	D13	D12	D11	D10	D9	D8
06H	ADRH	D23	D22	D21	D20	D20	D19	D18	D17
07H	ADCR0	ADRST	ADSLP	ADOFF	ADOR3	ADOR2	ADOR1	ADOR0	VREFS
08H	ADCR1	FLMS2	FLMS1	FLMS0	VRBUFN	VRBUFP	ADCDL	EOC	_
09H	ADCS	—		—	ADCK4	ADCK3	ADCK2	ADCK1	ADCK0



Address	Register Bit										
Audress	Name	7	6	5	4	3	2	1	0		
0AH	ADCTE	D7	D6	D5	D4	D3	D2	D1	D0		
0BH	DAH	D11	D10	D9	D8	D7	D6	D5	D4		
0CH	DAL					D3	D2	D1	D0		
0DH	DACC	DACEN	DACVRS						—		
0EH	SIMC0	SIMS				SIMDEB1	SIMDEB0		_		
10H	SIMTOC	SIMTOEN	SIMTOF	SIMTOS5	SIMTOS4	SIMTOS3	SIMTOS2	SIMTOS1	SIMTOS0		
11H	HIRCC						HIRCO	HIRCF	HIRCEN		
12H	Reserved, cannot be changed										

Internal Power Supply

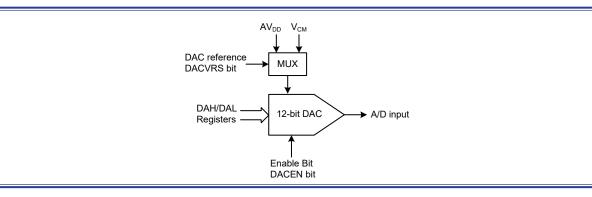
This 24-bit A/D Converter contains the VCM for the regulated power supply. The VCM can be used as the reference voltage for this 24-bit ADC module. The VCM function is controlled by the VCMEN bit and can be powered off to reduce the power consumption.

Reference Voltages

An internal voltage reference source, known as the VCM, is used as a converter reference. The VCM is sourced from a bandgap reference generator thus providing a temperature stable reference and has a output voltage level fixed at 1.25V. The VCM function is controlled by the VCMEN bit and can be switched off to reduce the power consumption.

The converter reference voltage range is supplied on two external reference pins, VREFP and VREFN. These offer a full reference voltage range of AV_{SS} to AV_{DD} . This externally supplied reference voltage can be attenuated by 0.5 or 0.25 using the VREFGN bits in the PGAC0 register.

An internal DAC is also provided as an additional reference voltage source. The DAC has two reference voltages which define the maximum value, supplied by either AV_{DD} or V_{CM} . The DAC 12bit value is setup using two data registers, DAL and DAH and selected using the DACVRS bit in the DACC register. The overall enable bit for the DAC is the DACEN bit in the DACC register.





• DAH Register - 0BH

Bit	7	6	5	4	3	2	1	0
Name	D11	D10	D9	D8	D7	D6	D5	D4
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0

Bit 7~0 **D11~D4**: DAC output control code

• DAL Register - 0CH

Bit	7	6	5	4	3	2	1	0
Name		—	—	—	D3	D2	D1	D0
R/W		—	—		R/W	R/W	R/W	R/W
POR		_	—	—	0	0	0	0

Bit 3~0 D3~D0: DAC output control code

Note: Writing to this register only writes to a shadow buffer. Not until data is written to the DAH register will the actual data be written into the DAL register.

DACC Register - 0DH

Bit	7	6	5	4	3	2	1	0
Name	DACEN	DACVRS	—			—	—	
R/W	R/W	R/W	—	—		—	—	—
POR	0	0		—		—	—	—

Bit 7	DACEN: DAC enable or disable control bit 0: Disable 1: Enable
Bit 6	DACVRS : DAC reference voltage selection 0: DAC reference voltage sourced from AV _{DD} 1: DAC reference voltage sourced from V _{CM}
Bit 5~0	Unimplemented, read as "0"

Power and Reference Control

The following table shows the overall control of the power and voltage sources.

Regist	er Bits	Output Voltage				
ADOFF	VCMEN	Bandgap	VCM			
1	0	Off	Disable			
1	1	On	Enable			
0	0	On	Disable			
0	1	On	Enable			

Power Control Table



Power Control Registers

• PWRC Register – 00H

	•							
Bit	7	6	5	4	3	2	1	0
Name	VCMEN	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0
Bit 7 VCMEN: VCM function enable control 0: Disable								
1: Enable If the VCM is disabled, there will be no power consumption and VCM output pin is								
			-		T	1		1 1

	floating.
Bit 6~0	D6~D0: Performance optimizing bits
	010_1000B: when ADCR1[FLMS2 ~ 0] = 000B ($f_{ADCK} = f_{MCLK}/30$)
	011_1100B: when ADCR1[FLMS2 ~ 0] = 010B ($f_{ADCK} = f_{MCLK}/12$)
	Others: Reserved

Oscillator

There is an internal HIRC oscillator in the 24-bit A/D converter module, which can provide the required A/D conversion clock source of 4.9152 MHz.

Oscillator Control Register

There is a control register for the 24-bit A/D Converter internal oscillator. Note that a full 16 clock cycle time is required for the internal HIRC oscillator to stabilise.

Bit	7	6	5	4	3	2	1	0
Name	—	—	—	—		HIRCO	HIRCF	HIRCEN
R/W	—	—	—	—		R/W	R	R/W
POR	—	—	—	—		0	0	1
Bit 7~3	Bit 7~3 Unimplemented, read as "0"							
Bit 2	HIRCO	: HIRC clo	ck output					
	This bit must be reserved at "0"							
Bit 1	0: Uns	HIRCF: HIRC oscillator stable flag 0: Unstable						
	1: Stable The HIRC stable time will spend 16 clocks when HIRCEN is enabled.							
Bit 0	HIRCE	N: HIRC o	scillator en	able contro	1			
	0: Dis	able						
	1: Enable							

• HIRCC Register - 11H



Input Signal Gain Control Amplifier – PGA

An internal programmable gain amplifier is provided to amplify the differential input signal before being converted. All input signals to the 24-bit analog to digital converter must pass through the PGA. This pre-processing of the input signal enables an optimal signal range to be setup to obtain a converted value with optimal resolution.

PGA Registers

The PGA is controlled using a series of registers to setup the gain value and also to select the input source.

• PGAC0 Register - 01H

	•	-						
Bit	7	6	5	4	3	2	1	0
Name	_	VGS1	VGS0	AGS1	AGS0	PGS2	PGS1	PGS0
R/W	—	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR		0	0	0	0	0	0	0
Bit 7	Unimple	emented, re	ad as "0"					
Bit 6~5								
Bit 4~3	 AGS1~AGS0: ADC converter PGAOP/PGAON differential input signal gain selection 00: ADGN = 1 01: ADGN = 2 (for Gain = 128 = PGAGN × ADGN = 64 × 2) 10: Reserved 11: Reserved 							
Bit 2~0	000: F 001: P 010: P 011: P 100: P 101: P 110: P 111: R	PGAGN = 1 PGAGN = 2 PGAGN = 4 GAGN = 8 PGAGN = 1 GAGN = 3 GAGN = 6 eserved	6 2	ifferential o	shannel inp	ut gain sele	ction	
	egister –		_		•	•		
Bit	7	6	5	4	3	2	1	0
Name		INIS	INX1	INX0	DCSET2	DCSET1	DCSET0	
R/W		R/W	R/W	R/W	R/W	R/W	R/W	

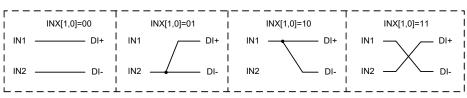
DIL	1	0	อ	4	3	2	I	U
Name	—	INIS	INX1	INX0	DCSET2	DCSET1	DCSET0	—
R/W		R/W	R/W	R/W	R/W	R/W	R/W	
POR	—	0	0	0	0	0	0	—

Bit 7 Unimplemented, read as "0".

Bit 6 INIS: Selected input terminals IN1/IN2 internal connection 0: Not connected 1: Connected



Bit 5~4 **INX1, INX0**: The selected input ends, IN1/IN2 and the PGA differential input ends, DI+/DI- connection control bits



Bit 3~1

DCSET2~DCSET0: Differential input signal PGAOP/PGAON offset selection 000: DCSET = +0V 001: DCSET = +0.25 × Δ VR_I 010: DCSET = +0.5 × Δ VR_I 011: DCSET = +0.75 × Δ VR_I 100: DCSET = +0V 101: DCSET = -0.25 × Δ VR_I 110: DCSET = -0.5 × Δ VR_I 111: DCSET = -0.75 × Δ VR_I

The voltage, ΔVR_I , is the differential reference voltage which is amplified by the specific gain selection based on the selected inputs.

Bit 0 Unimplemented, read as "0"

PGA Input Channel Selection

In addition to the external analog input to be measured by the converter, there are several other internal analog voltage lines which can be connected to the converter. These come from a range of sources such as the temperature sensor and are normally used for calibration purposes.

	•							
Bit	7	6	5	4	3	2	1	0
Name	_	—	CHSN2	CHSN1	CHSN0	CHSP2	CHSP1	CHSP0
R/W		—	R/W	R/W	R/W	R/W	R/W	R/W
POR		_	0	0	0	0	0	0

• PGACS Register - 03H

Bit 7~6 Unimplemented, read as "0"

Bit 5~3 CHSN2~CHSN0: PGA negative input end IN2 selection

000: AN1 001: AN3 010: Reserved 011: Reserved 100: V_{DACO} 101: AV_{SS}

110: V_{CM}

111: V_{TSN} – Temperature sensor negative output

These bits are used to select the negative input, IN2. If the IN2 input is selected as a single end input, the V_{CM} voltage must be selected as the positive input on IN1 for single end input applications. It is recommended that when the V_{TSN} signal is selected as the negative input, the V_{TSP} signal should be selected as the positive input for proper operations.





Bit 2~0	CHSP2~CHSP0: Positive input end IN1 selection
	000: AN0
	001: AN2
	010: Reserved
	011: Reserved
	100: V _{DACO}
	101: Reserved
	110: V _{CM}
	111: V_{TSP} – Temperature sensor positive output

These bits are used to select the positive input, IN1. If the IN1 input is selected as a single end input, the V_{CM} voltage must be selected as the negative input on IN2 for single end input applications. It is recommended that when the V_{TSP} signal is selected as the positive input, the V_{TSN} signal should be selected as the negative input for proper operations.

24-Bit Analog to Digital Converter Operation

The 24-bit analog to digital converter received a differential analog signal from the PGA output and converts in using a Delta Sigma converter into a 24-bit digital value. The overall operation of the converter is controlled by a series of control registers.

Bit	7	6	5	4	3	2	1	0
Name	ADRST	ADSLP	ADOFF	ADOR3	ADOR2	ADOR1	ADOR0	VREFS
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	1	0	0	0	0	0
Bit 7	0: Dis 1: Ena This bit low for will be	able uble is used to A/D norma reset and t	reset the A al operation he current	/D convert ns. Howeve A/D conve	nable contro er internal r, if set hig rted data v ntil this bit	digital SIN h, the inter vill be abor	nal digital rted. A nev	SINC filter
Bit 6	ADSLP 0: Nor 1: Slee This bit when th converte normally set high will be s	A/D conv rmal mode ep mode is used to o e A/D conv er is power y. However as the A/D	determine v verter is pov ed on and t, the A/D of converter f except the	mode enab whether the wered on by the ADSLI converter w has been p PGA and	e A/D convo y setting the bit is low yill enter the owered on.	erter enters e ADOFF l , the A/D o e sleep moo The whole	the sleep n bit low. Wh converter w de if the Al A/D converter	en the A/D vill operate DSLP bit is erter circuit
Bit 5	ADOFI 0: Pov	F: A/D conv		-	n/off contro	bl		

• ADCR0 Register - 07H



		to zero t be switc consum- be an im Setting	to enable the ched off rec e a limited aportant com	he A/D con- lucing the amount of nsideration F bit high v	verter. If th device pow power, even in power so will power	e bit is set er consump n when not ensitive bat	high then t ption. As the executing tery power	he A/D cor he A/D cor a conversio ed applicati	be cleared averter will nyerter will n, this may tons. regardless		
	Bit 4~1					sampling ra	te selection	1			
			-	-	SR = 32768						
		0001: Oversampling rate $OSR = 16384$									
		0010: Oversampling rate OSR = 8192 0011: Oversampling rate OSR = 4096									
		0100: Oversampling rate OSR = 2048									
			Oversampli	-							
		0110:	Oversampl	ing rate OS	R = 512						
			Oversampli								
			Oversampl		SR = 128						
		0 11101	s: Reserved								
	Bit 0				-	e pair select	tion				
				-	pair – V _{CM}						
		1: Ext	ernal refere	ence voltage	$e pair - V_{RI}$	$_{\rm EFP}$ & ${ m V}_{ m REFN}$					
•	ADCR1 R	egister -	08H								
	Bit	7	6	5	4	3	2	1	0		
	Name	FLMS2	FLMS1	FLMS0	VRBUFN	VRBUFP	ADCDL	EOC	_		
	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	—		
	POR	0	0	0	0	0	0	0	_		

FLMS2~FLMS0 : A/D converter clock divided ratio selection 000: $f_{ADCK} = f_{MCLK}/30$, N = 30 010: $f_{ADCK} = f_{MCLK}/12$, N = 12 Others: Reserved
VRBUFN : A/D converter negative reference voltage input (VRN) buffer control 0: Disable input buffer and enable bypass function 1: Enable input buffer and disable bypass function
VRBUFP : A/D converter positive reference voltage input (VRP) buffer control 0: Disable input buffer and enable bypass function 1: Enable input buffer and disable bypass function
ADCDL: A/D converted data latch function enable control 0: A/D converted data updated 1: A/D converted data not updated
If the A/D converted data latch function is enabled, the latest converted data value will be latched and not be updated by any subsequent converted results until this function is disabled. Although the converted data is latched into the data registers the A/D converter circuits remain operational and EOC flag will not change state. It is recommended that this bit should be set high before reading the converted data in the ADRL, ADRM and ADRH registers. After the converted data has been read out the bit can then be cleared to zero to disable the A/D converter data latch function and allow further conversion values to be stored. In this way, the possibility of



obtaining undesired data during A/D converter conversions can be prevented.

Bit 1	EOC: End of A/D conversion flag
	0: A/D conversion in progress
	1: A/D conversion ended
	This flag will be automatically set high by the hardware when a conversion process
	has completed but must be cleared by the application software.
Bit 0	Unimplemented, read as "0"

A/D Data Rate Definition

The Delta Sigma ADC data rate can be calculated by the equation list below.

Data Rate = f_{ADCK} / OSR

 $= \left(f_{\text{MCLK}} / N \right) / \text{OSR}$

 $= f_{MCLK} / (N \times OSR)$

 $f_{\text{ADCK}}\text{:}\;f_{\text{MCLK}}/N$

 $f_{\text{MCLK}}\text{:}\;f_{\text{ADC_CLK}} \text{ or } f_{\text{ADC_CLK}}/2/(\text{ADCK}+1) \text{ using the ADCK bit field.}$

N: 30 or 12 determined by the FLMS bit field.

OSR: Oversampling rate determined by the ADOR field.

For example; if a data rate of 10Hz is desired. An f_{MCLK} clock source with a frequency of 4.9152 MHz ADC can be selected. Then set the FLMS field to "000" to obtain an "N" equal to 30. Finally, set the ADOR field to "0001" to select an oversampling rate equal to 16384. Therefore, the Data Rate = $4.9152 \text{ MHz} / (30 \times 16384) = 10 \text{ Hz}.$

Note that the A/D converter has a notch rejection function for an AC power supply with a frequency of 50 Hz or 60 Hz when the data rate is equal to 10Hz.

A/D Converter Clock Source

The clock source for the A/D converter should be typically fixed at a value of 4.9152 MHz, which originates from the 24-bit ADC clock $f_{ADC_{CLK}}$. This can be chosen to be either $f_{ADC_{CLK}}$ or a subdivision of $f_{ADC_{CLK}}$. The division ratio value is determined by the ADCK4 ~ ADCK0 bits in the ADCS register to obtain a 4.9152 MHz clock source for the ADC.

Internal OSC = 4.9152 MHz, $f_{ADCK} = f_{MCLK}/30$.

Data Rate (Hz)	ADCK4 ~ 0	ADOR3 ~ 0	FLMS2 ~ 0
10	11111	0001	000

Internal OSC = 4.9152 MHz, $f_{ADCK} = f_{MCLK}/12$.

Data Rate (Hz)	ADCK4 ~ 0	ADOR3 ~ 0	FLMS2 ~ 0
25	11111	0001	010



ADCS Register – 09H

Bit	7	6	5	4	3	2	1	0
Name	—	—	—	ADCK4	ADCK3	ADCK2	ADCK1	ADCK0
R/W	—	—	—	R/W	R/W	R/W	R/W	R/W
POR				0	0	0	0	0

Bit 7~5 Unimplemented, read as "0"

Bit 4~0

ADCK4~ADCK0: 24-bit A/D converter clock source f_{MCLK} divided ratio selection 00000~11110: $f_{MCLK} = f_{ADC_CLK}/2/(ADCK[4:0] + 1)$

111111: $f_{MCLK} = f_{ADC \ CLK}$

• ADCTE Register - 0AH

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	1	1	1	0	0	1	0	0

Bit 7~0 Reserved bits, should be fixed as 1110 0111B.

A/D Operating Modes

The 24-bit A/D Converter has four operating modes, which are the Normal mode, Power down mode, Sleep mode and Reset mode. These modes are controlled by a combination of the ADOFF, ADSLP and ADRST bits in the ADCR0 register as shown in the accompanying table. The ADOFF controls the overall on/off condition and if high will power down the A/D converter to reduce power. When the ADOFF bit is low, the converter will be powered on and the ADSLP bit will determine if the converter is in the normal operating mode or in the sleep mode.

ADOFF	ADSLP	ADRST	Operating Mode	Description
1	х	x	Power down mode	Bandgap off, PGA off, ADC off, Temperature sensor off, VRN/VRP buffer off, SINC filter off
0	1	х	Sleep mode	Bandgap on, PGA on, ADC off, Temperature sensor off, VRN/VRP buffer off, SINC filter on
0	0	0	Normal mode	Bandgap on, PGA on, ADC on, Temperature sensor on/off, VRN/VRP buffer on/off, SINC filter on
0	0	1	Reset mode	Bandgap on, PGA on, ADC on, Temperature sensor on/off, VRN/VRP buffer on/off, SINC filter Reset

"x" unknown

A/D Operating Mode Summary

Note: 1. The VCM generator can be switched on or off by configuring the VCMEN bit.

- 2. The Temperature sensor can be switched on or off by configuring the CHSN[2:0] or CHSP[2:0] bits.
- 3. The VRN buffer can be switched on or off by configuring the VRBUFN bit while the VRP buffer can be switched on or off by configuring the VRBUFP bit.

A/D Conversion Process

To enable the A/D Converter, the first step is to disable the ADC power down and sleep mode by clearing the ADOFF and ADSLP bits to make sure the A/D Converter is powered up. The ADRST bit in the ADCR0 register is used to start and reset the A/D converter after power on. To set



ADRST bit from low to high and then low again, an analog to digital converted data in SINC filter will be initiated. After this setup is complete, the A/D Converter is ready for operation. These three bits are used to control the overall start operation of the internal analog to digital converter.

The EOC bit in the ADCR1 register is used to indicate when the analog to digital conversion process is complete. This bit will be automatically set to "1" by the Hardware after a conversion cycle has ended. The ADC converted data will be updated continuously by new converted data. If the ADC converted data latch function is enabled, the latest converted data will be latched and the following new converted data will be discarded until this data latch function is disabled.

The differential reference voltage supply to the A/D Converter can be supplied from either the internal power supply, V_{CM} and AV_{SS} , or from an external reference source supplied on pins VREFP and VREFN. The desired selection is made using the VREFS bit in the ADCR0 register.

Summary of A/D conversion steps

• Step 1

Enable the power VCM for PGA and ADC.

• Step 2

Select the PGA, ADC, reference voltage gains by PGAC0 register.

• Step 3

Select the PGA settings for input connection, VCM voltage level and buffer option by PGAC1 register.

• Step 4

Select the required A/D conversion clock source 4.9152 MHz by correctly programming bits ADCK4 ~ ADCK0 in the ADCS register.

• Step 5

Select output data rate by cofiguring the ADOR[2:0] bits in the ADCR0 register and FLMS[2:0] bits in the ADCR1 register.

• Step 6

Select which channel is to be connected to the internal PGA by correctly programming the CHSP2 ~ CHSP0 and CHSN2 ~ CHSN0 bits which are also contained in the PGACS register.

• Step 7

Release the power down mode and sleep mode by clearing the ADOFF and ADSLP bits in ADCR0 register.

• Step 8

Reset the A/D by setting the ADRST to high in the ADCR0 register and clearing this bit to zero to release reset status.

• Step 9

To check when the analog to digital conversion process is complete, the EOC bit in the ADCR1 register can be polled. The conversion process is complete when this bit goes high. When this occurs the A/D data registers ADRL, ADRM and ADRH can then be read to obtain the conversion value.



A/D Transfer Function

As the converted value is 24-bits its full-scale converted digitised value has a decimal value of 8388607 to -8388608. The converted data format is formed by a two's complement binary value. The MSB of the converted data is the signed bit. Since the full-scale analog input value is equal to the amplified value of the VCM or differential reference input voltage, ΔVR_I , selected by the VREFS bit in ADCR0 register, this gives a single bit analog input value of ΔVR_I divided by 8388608.

 $1 \text{ LSB} = \Delta \text{VR}_{I}/8388608$

The A/D Converter input voltage value can be calculated using the following equation:

 $\Delta SI I = (PGAGN \times ADGN \times \Delta DI \pm) + DCSET$

 $\Delta VR_I = VREFGN \times \Delta VR \pm$

ADC_Conversion_Data = $(\Delta SI_I / \Delta VR_I) \times K$

Where K is equal to 2^{23} .

Notes: 1. The PGAGN, ADGN, VREFGN values are determined by the PGS, AGS, VGS control bits.

- 2. Δ SI_I is the differential input signal after amplification and offset adjustment
- 3. PGAGN: Programmable Gain Amplifier gain
- 4. ADGN: A/D Converter gain
- 5. VREFGN: Reference voltage gain
- 6. Δ DI±: Differential input signal derived from external channels or internal signals
- 7. DCSET: Offset voltage
- 8. ΔVR±: Differential reference voltage
- 9. ΔVR_I : Differential reference input voltage after amplification

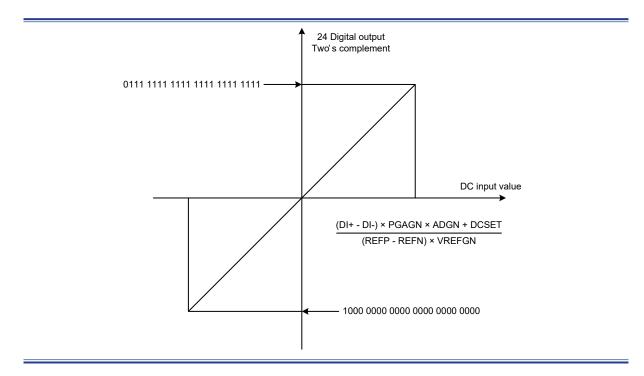
Due to the digital system design of the converter, the maximum A/D converted value is 8388607 and the minimum value is -8388608, therefore the centre value is 0. The ADC_Conversion_Data equation illustrates this range of converted data variation.

Converted Data 2's Compliment Hex Value	Decimal Value		
0x7FFFFF	8388607		
0x800000	-8388608		

A/D Conversion Data Range

The following diagram shows the relationship between the DC input value and the ADC converted data which is presented in Two's Complement format.





A/D Converted Data

The 24-bit A/D converter data is stored in three individual registers, ADRL, ADRM and ADRH. The converted data is related to the input voltage and the PGA selection setup and is generated in a two's complement binary code formal. The length of this output code is 24 bits and the MSB is a signed bit. When the MSB is "0", this indicates that the input is "positive", while if the MSB is "1", this indicates that the input is "negative". The maximum value is 8388607 and the minimum value is -8388608. If the input signal exceeds the maximum value, the converted data is limited to -8388608.

• ADRL Register - 04H

Bit	7	6	5	4	3	2	1	0
Name	D7	D6	D5	D4	D3	D2	D1	D0
R/W	R	R	R	R	R	R	R	R
POR	х	х	х	х	х	х	х	х

Bit 7~0

A/D conversion data register bit 7~bit 0

• ADRM Register - 05H

Bit	7	6	5	4	3	2	1	0
Name	D15	D14	D13	D12	D11	D10	D9	D8
R/W	R	R	R	R	R	R	R	R
POR	х	х	х	х	х	х	х	х

Bit 7~0 A/D conversion data register bit 15~bit 8



• ADRH Register - 06H

Bit	7	6	5	4	3	2	1	0
Name	D23	D22	D21	D20	D19	D18	D17	D16
R/W	R	R	R	R	R	R	R	R
POR	х	х	х	х	х	х	х	х

Bit 7~0 A/D conversion data register bit 23~bit 16

Converting the Digital Value to a Voltage

The analog voltage value can be recovered using the following equations:

If the MSB = 0 for positive value converted data: Input Voltage = $\frac{(Converted_data) \times LSB - DCSET}{PGAGN \times ADGN}$ If the MSB = 1 for negative converted data: Input voltage = $\frac{(Two's_complement_of_Converted_data) \times LSB - DCSET}{PGAGN \times ADGN}$

Note: Two's complement = One's complement + 1

Temperature Sensor

The 24-bit A/D converter module includes a fully internal temperature sensor to allow for compensation due to temperature effects. By selecting the PGA input channels to V_{TSN} and V_{TSN} signals, the A/D Converter can obtain temperature information and then use the result to compensate the A/D converted data to minimise the effects of temperature.

Effective Number of Bits – ENOB

Although the analog to digital converter is a 24-bit type various factors such as the PGA gain and the data rate affect the actual number of effective number of converted bits.

Programming Considerations

During microcontroller operations where the A/D converter is not being used, the A/D internal circuitry can be switched off to reduce power consumption, by setting bit ADOFF high in the ADCR0 register. When this happens, the internal A/D converter circuits will not consume power irrespective of what analog voltage is applied to their input lines.

When writing to the DAC registers, DAH and DAL, note that this must be carried out in a special sequence. This is because when writing to the DAL register, the data is only written into a shadow buffer register. Only when data is written to the DAH register will data in the shadow buffer be transferred to the DAL register. Therefore when writing data to the DAC registers first write data to the DAL register and then to the DAH register.

External Interface Communication

The 24-bit A/D converter communicates with external hardware using its internal I^2C interface. Originally developed by Philips, the I^2C interface is a two line low speed serial interface for synchronous serial data transfer. With the advantage of only two lines for communication, a



relatively simple communication protocol and the ability to accommodate multiple devices on the same bus has made it an extremely popular interface type for many applications.

I²C Interface Operation

The I²C serial interface is a two line interface, a serial data line, SDA, and serial clock line, SCL. As many devices may be connected together on the same bus, their outputs are both open drain types. For this reason it is necessary that external pull-high resistors are connected to these outputs. Note that no chip select line exists, as each device on the I²C bus is identified by a unique address which will be transmitted and received on the I²C bus. When two devices communicate with each other on the bidirectional I²C bus, one is known as the master device and one as the slave device. Both master and slave can transmit and receive data, however, it is the master device that has overall control of the bus, and it is only the master that will drive the SCL clock line. This 24-bit ADC module only operates in the slave mode, and will therefore only operate in response to the master. There are two methods for this 24-bit ADC module to transfer data on the I²C bus, the slave transmit mode and the slave receive mode.

Several registers control the overall operation of the I²C bus interface.

I²C Address and Register Write/Read

I²C Address Selection

As this 24-bit ADC module only operates as a slave, and as it may be connected to a common I^2C bus along with other I^2C devices, it will require a specific address for it to be communicated to by the master. The address of 24-bit ADC module is fixed at 0xD0.

• SIMC0 Register – 0EH

Bit	7	6	5	4	3	2	1	0
Name	SIMS	—	—		SIMDEB1	SIMDEB0	—	—
R/W	R/W	_	—		R/W	R/W	—	—
POR	0	_			0	0	—	_

Bit 7 SIMS:

0: Normal operation

1: Results in unpredictable behavior

This bit must be kept at a zero value for normal operation

Bit 6~4 Unimplemented, read as "0"

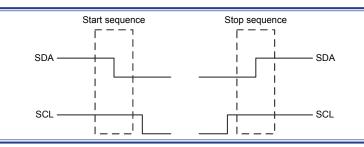
Bit 3~2 **SIMDEB1~SIMDEB0**: 1²C debounce time selection 00: No debounce 01: 2 ADC clock debounce 10: 4 ADC clock debounce 11: 4 ADC clock debounce

Bit 1~0 Unimplemented, read as "0"

Start and Stop Operations

Normally the SDA line can only change when the SCL line is low. There are two exceptions however and that is for the Start and Stop operations, where the SCL line will be forced high by the master and the SDA line will change sate. As the diagram shows when the SCL line is high, a high to low SDA line transition indicates a start operation and a low to high SDA line transition indicates a stop operation.





I²C Bus Data Transfer

Data is transferred on the I²C bus in 8 bit packets, first transmitting the MSB which is the most significant bit and lastly the LSB bit, the least significant bit. When the data has been setup on the SDA line, the SCL line then generates a high pulse to latch the data. When the SCL line is high the SDA line is not permitted to change state. After 8-bits have been transmitted, the device will then send a 9th bit which is the acknowledge bit. Therefore in total there are 9 bits transmitted and subsequently 9 SCL clock pulses to transfer each 8-bits or byte of data. When the receiving device sends back a low ACK bit, this is to acknowledge that it has received the 8-bits of data and is ready to receive another byte. If a high ACK bit is sent back, this indicates that it is unable to receive any further data and the master should then send a stop sequence.

I²C Register Write/Read

Write Process

Bit	7	6	5	4	3	2	1	0		7	6	5	4	3	2	1	0		7	6	5	4	3	2	1	0		
Start		De	evice	e Ao	ddre	ess		Write	ACK		R	legis	ster	Ado	dres	s		ACK			Re	giste	er D	ata			ACK	Stop

Read Process

Bit	7 6 5 4 3 2 1	0		76	5	4	3	2	1	0			7	6	5	4	3	2	1	0		7	6	5	4	1 3	3	2	1	0			
Start	Device Address	Write	ACK	Re	gis	ter	Ad	ldre	ess	S	ACK	Start	D	ev	ice	A e	dd	re	ss	Read	ACK		F	leç	jist	ter	D	at	а		ACK	S	top

I²C Bus Start Signal

The START signal can only be generated by the master device connected to the I^2C bus and not by the slave device. This START signal will be detected by all devices connected to the I^2C bus. A START condition occurs when a high to low transition on the SDA line takes place when the SCL line remains high.

Slave Address

The transmission of a START signal by the master will be detected by all devices on the I²C bus. To determine which slave device the master wishes to communicate with, the address of the slave device will be sent out immediately following the START signal.

I²C Bus Slave Address Acknowledge Signal

After the master has transmitted a calling address, any slave device on the I²C bus, whose own internal address matches the calling address, must generate an acknowledge signal. The acknowledge signal will inform the master that a slave device has accepted its calling address. If no acknowledge signal is received by the master then a STOP signal must be transmitted by the master to end the communication.



I²C Bus Data and Acknowledge Signal

The transmitted data is 8-bits wide and is transmitted after the slave device has acknowledged receipt of its slave address. The order of serial bit transmission is the MSB first and the LSB last. After receipt of 8-bits of data, the receiver must transmit an acknowledge signal, level 0, before it can receive the next data byte. If the slave transmitter does not receive an acknowledge bit signal from the master receiver, then the slave transmitter will release the SDA line to allow the master to send a STOP signal to release the I²C Bus.

I²C Timeout Function

The I²C interface includes a timeout function which is controlled by a single register. This register sets the overall enable/disable function as well as the timeout value in ADC clock units. Determining whether the I²C bus has timed out is implemented by reading the SIMTOF bit. This bit will be automatically set high when the I²C bus times out, but needs to be cleared manually by the application program.

Bit	7	6	5	4	3	2	1	0
Name	SIMTOEN	SIMTOF	SIMTOS5	SIMTOS4	SIMTOS3	SIMTOS2	SIMTOS1	SIMTOS0
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
POR	0	0	0	0	0	0	0	0
Bit 7	SIMTO 0: Dis 1: Ena	able	ne-out cont	trol				
Bit 6	0: Not 1: Occ	F: I ² C time coccurred curred is set by tim	e-out flag ne-out func	tion and is	cleared by	the applicat	tion program	m.
Bit 5~0	The I ² C	Time-Out	OS0 : I ² C ti clock sourc time is ([SI	e is f _{ADC_CL}	_K /32. (f _{sub} =	_		

• SIMTOC Register - 10H



5 Pin Assignment

									48 LC	QFP-A									
				PB8	PB7	PB3	PB2	AN2	AN3	AN1	ANO	VCM	AVSS/ VREFN	AVDD /VREFP	DRDYB		AF0 (Default)		
	AF0 (Default)		~	48	47	46	45	44	43	42	41	40	39	38	37			AF0 (Default)	AF1
	(, , , , , , , , , , , , , , , ,		C	VDD	VDD	VDD	VDD	VDD 24	VDD 24	VDD 24	VDD 24	VDD 24	VDD 24	VDD 24	VDD 24			(, _ ,	
Γ	VDDA	1	AP													VDD 24	36	SDA	
	VSSA	2	AP			PVD) Powe	er Pad							VDD 24	35	SCL	
	PA0	3	VDD			VDD	.		_							VDD 24	34	DVDD	
	PA1	4	VDD			24	24 b	oit A/D	Power	Pad						VDD 24	33	DVSS	
	PA2	5	VDD			AP	Ana	log Po	wer Pa	d						VDD	32	PB1	
	PA3	6	VDD			P15	15	V Pow	er Pad							VDD	31	PB0	
	PA4	7	VDD													VDD	30	SWDIO	PA13
	PA5	8	VDD			VDD	VDD) Digita	al & An	alog I/0) Pad					VDD	29	SWCLK	PA12
	PA6	9	VDD			VDD) Digita	al I/O P	ad						VDD	28	PA11	
	PA7	10	VDD					3								VDD	27	PA10	
	PC4	11	VDD			VDD	VDE) Doma	ain Pac	I						VDD	26	PA9_BOOT	
	PC5	12	VDD													VDD	25	PA8	
				P15	PVDD	PVDD	VDD	VDD	VDD	VDD	VDD	VDD	VDD	VDD	VDD				
				13	14	15	16	17	18	19	20	21	22	23	24				
				CLDO	VDD	VSS	nRST	PB9	X32KIN	X32KOUT	RTCOUT	XTALIN	XTALOUT	PB15	PC0		AF0 (Default)		
									PB10	PB11	PB12	PB13	PB14				AF1		





Table 3. Pin Assignment

Package							Alternat	e Func	tion M	appin	g					
Гаскауе	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
48LQFP	System Default	GPIO	ADC	N/A	MCTM /GPTM	SPI	USART /UART	I ² C	N/A	N/A	N/A	N/A	N/A	PWM	N/A	System Other
1	VDDA															
2	VSSA															
3	PA0		ADC_ IN2		GT_CH0	SPI1_ SCK	USR_ RTS	I2C1_ SCL								
4	PA1		ADC_ IN3		GT_CH1	SPI1_ MOSI	USR_ CTS	I2C1_ SDA								
5	PA2		ADC_ IN4		GT_CH2	SPI1_ MISO	USR_TX									
6	PA3		ADC_ IN5		GT_CH3	SPI1_ SEL	USR_RX									
7	PA4		ADC_ IN6		GT_CH0	SPI0_ SCK	UR1_TX	I2C0_ SCL								
8	PA5		ADC_ IN7		GT_CH1	SPI0_ MOSI	UR1_RX	I2C0_ SDA								
9	PA6		ADC_ IN8		GT_CH2	SPI0_ MISO										
10	PA7		ADC_ IN9		GT_CH3	SPI0_ SEL										
11	PC4		ADC_ IN10				USR_TX							PWM1_ CH0		
12	PC5		ADC_ IN11				USR_RX							PWM1_ CH1		
13	CLDO															
14	VDD															
15	VSS															
16	nRST															
17	PB9				MT_ CH3									PWM1_ CH2		WAKEUP1
18	X32KIN	PB10			GT_CH0	SPI1_ SEL	USR_TX							PWM1_ CH3		
19	X32KOUT	PB11			GT_CH1	SPI1_ SCK	USR_RX							PWM0_ CH3		
20	RTCOUT	PB12				SPI0_ MISO	UR0_RX							PWM0_ CH0		WAKEUP0
21	XTALIN	PB13					UR0_TX	I2C0_ SCL								
22	XTALOUT	PB14					UR0_RX	I2C0_ SDA								
23	PB15				MT_ CH0	SPI0_ SEL		I2C1_ SCL						PWM0_ CH1		
24	PC0				MT_ CH0N	SPI0_ SCK		I2C1_ SDA						PWM0_ CH2		
25	PA8						USR_TX							PWM1_ CH3		
26	PA9_ BOOT					SPI0_ MOSI								PWM1_ CH0		CKOUT
27	PA10				MT_ CH1	SPI0_ MOSI	USR_RX							PWM0_ CH1		
28	PA11				MT_ CH1N	SPI0_ MISO								PWM0_ CH2		
29	SWCLK	PA12														
30	SWDIO	PA13														
31	PB0				MT_ CH1	SPI1_ MOSI	USR_TX	I2C0_ SCL						PWM0_ CH1		
32	PB1				MT_ CH1N	SPI1_ MISO	USR_RX	I2C0_ SDA						PWM1_ CH1		



							Alternat	e Func	tion M	appin	g					
Package	AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
48LQFP	System Default	GPIO	ADC	N/A	MCTM /GPTM	SPI	USART /UART	I ² C	N/A	N/A	N/A	N/A	N/A	PWM	N/A	System Other
33	DVSS															
34	DVDD															
35	SCL															
36	SDA															
37	DRDYB															
38	AVDD															
38	VREFP															
39	AVSS															
39	VREFN															
40	VCM															
41	AN0															
42	AN1															
43	AN3															
44	AN2															
45	PB2				MT_ CH2	SPI0_ SEL	UR1_TX							PWM0_ CH2		CKIN
46	PB3				MT_ CH2N	SPI0_ SCK	UR1_RX							PWM1_ CH2		
47	PB7		ADC_ IN0		MT_ CH1	SPI0_ MISO	UR0_TX	I2C1_ SCL						PWM0_ CH3		
48	PB8		ADC_ IN1		MT_ CH1N	SPI0_ SEL	UR0_RX	I2C1_ SDA						PWM1_ CH3		

Table 4. Pin Description

Pin Number	Pin	T urne ⁽¹⁾	I/O	Output	Description
48LQFP	Name	Type ⁽¹⁾	Structure ⁽²⁾	Driving	Default Function (AF0)
1	VDDA	Р	—		Analog voltage for ADC
2	VSSA	Р	—		Ground reference for the ADC
3	PA0	AI/O	5V	4/8/12/16 mA	PA0
4	PA1	AI/O	5V	4/8/12/16 mA	PA1
5	PA2	AI/O	5V	4/8/12/16 mA	PA2
6	PA3	AI/O	5V	4/8/12/16 mA	PA3
7	PA4	AI/O	5V	4/8/12/16 mA	PA4
8	PA5	AI/O	5V	4/8/12/16 mA	PA5
9	PA6	AI/O	5V	4/8/12/16 mA	PA6
10	PA7	AI/O	5V	4/8/12/16 mA	PA7
11	PC4	AI/O	5V	4/8/12/16 mA	PC4
12	PC5	AI/O	5V	4/8/12/16 mA	PC5
13	CLDO	Р	_	_	Core power LDO 1.5 V output It is recommended to connect a 2.2 μ F capacitor as close as possible between this pin and VSS.
14	VDD	Р	—		Voltage for digital I/O
15	VSS	Р	—		Ground reference for digital I/O
16	nRST ⁽³⁾	I	5V_PU		External reset pin



Pin Number	Pin	- (1)	I/O	Output	Description
48LQFP	Name	Type ⁽¹⁾	Structure ⁽²⁾	Driving	Default Function (AF0)
17	PB9 ⁽³⁾	I/O (V _{DD})	5V	4/8/12/16 mA	PB9
18	PB10 ⁽³⁾	AI/O (V _{DD})	5V	4/8/12/16 mA	X32KIN
19	PB11 ⁽³⁾	AI/O (V _{DD})	5V	4/8/12/16 mA	X32KOUT
20	PB12 ⁽³⁾	I/O (V _{DD})	5V	4/8/12/16 mA	RTCOUT
21	PB13	AI/O	5V	4/8/12/16 mA	XTALIN
22	PB14	AI/O	5V	4/8/12/16 mA	XTALOUT
23	PB15	I/O	5V	4/8/12/16 mA	PB15
24	PC0	I/O	5V	4/8/12/16 mA	PC0
25	PA8	I/O	5V	4/8/12/16 mA	PA8
26	PA9	I/O	5V_PU	4/8/12/16 mA	PA9_BOOT
27	PA10	I/O	5V	4/8/12/16 mA	PA10
28	PA11	I/O	5V	4/8/12/16 mA	PA11
29	PA12	I/O	5V_PU	4/8/12/16 mA	SWCLK
30	PA13	I/O	5V_PU	4/8/12/16 mA	SWDIO
31	PB0	I/O	5V	4/8/12/16 mA	PB0
32	PB1	I/O	5V	4/8/12/16 mA	PB1
33	DVSS	Р	_		24-bit ADC digital negative power supply
34	DVDD	Р	_		24-bit ADC digital power supply
35	SCL	I	_		24-bit ADC internal I ² C interface clock line
36	SDA	I/O			24-bit ADC internal I ² C interface data line
37	DRDYB	0	_	_	24-bit ADC data ready indication: indicates valid data by going low
38	AVDD	Р			24-bit ADC analog power supply
38	VREFP	AI	—		24-bit ADC positive reference input voltage
39	AVSS	Р			24-bit ADC analog negative power supply
39	VREFN	AI	_		24-bit ADC negative reference input voltage
40	VCM	AO	_	_	24-bit ADC internal Common mode voltage output
41	AN0	AI	—	_	24-bit ADC input channel 0
42	AN1	AI	_	_	24-bit ADC input channel 1
43	AN3	AI	—	—	24-bit ADC input channel 3
44	AN2	AI	—	—	24-bit ADC input channel 2
45	PB2	I/O	5V	4/8/12/16 mA	PB2
46	PB3	I/O	5V	4/8/12/16 mA	PB3
47	PB7	AI/O	5V	4/8/12/16 mA	PB7
48	PB8	AI/O	5V	4/8/12/16 mA	PB8

Note: 1. I = input, O = output, A = Analog port, P = power supply, $V_{DD} = V_{DD}$ Power.

2. 5V = 5 V operation I/O type, PU = Pull-up.

3. These pins are located at the $V_{\mbox{\scriptsize DD}}$ power domain.



6 Electrical Characteristics

Absolute Maximum Ratings

The following table shows the absolute maximum ratings of the device. These are stress ratings only. Stresses beyond absolute maximum ratings may cause permanent damage to the device. Note that the device is not guaranteed to operate properly at the maximum ratings. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Min.	Max.	Unit
V _{DD}	External Main Supply Voltage	V _{SS} - 0.3	V _{SS} + 5.5	V
V _{DDA}	External Analog Supply Voltage	V _{SSA} - 0.3	V _{SSA} + 5.5	V
DV_{DD}	24-bit A/D Converter Module Supply Voltage	DV _{SS} - 0.3	DV _{SS} + 6.0	V
V _{IN}	Input Voltage on I/O	V _{SS} - 0.3	V _{DD} + 0.3	V
T _A	Ambient Operating Temperature Range	-40	+85	°C
T _{STG}	Storage Temperature Range	-55	+150	°C
TJ	Maximum Junction Temperature		125	°C
PD	Total Power Dissipation		500	mW
V _{ESD}	Electrostatic Discharge Voltage – Human Body Mode	-4000	+4000	V

Table 5. Absolute Maximum Ratings

Recommended DC Operating Conditions

Table 6. Recommended DC Operating Conditions

		T _A = 25 °C	C, unles	s other	wise sp	ecified.
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V_{DD}	Operating Voltage	—	2.5	5.0	5.5	V
V_{DDA}	Analog Operating Voltage	—	2.5	5.0	5.5	V

On-Chip LDO Voltage Regulator Characteristics

Table 7. LDO Characteristics

T_A = 25 °C, unless otherwise specif
--

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V_{LDO}	Internal Regulator Output Voltage	$V_{DD} \ge 2.5$ V Regulator input @ I _{LDO} = 35 mA and voltage variant = ±5 %, After trimming	1.425	1.5	1.57	V
I _{LDO}	Output Current	V_{DD} = 2.5 V Regulator input @ V_{LDO} = 1.5 V		30	35	mA
C _{LDO}	External Filter Capacitor Value for Internal Core Power Supply	The capacitor value is dependent on the core power current consumption	1	2.2	_	μF



Power Consumption

			Min.	Max.		
Symbol	Parameter	Conditions	T _A = 25 °C	T _A = 25 °C	T _A = 85 °C	Unit
	Supply Current (Run Mode)	V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 20 MHz, f_{PCLK} = 20 MHz, all peripherals enabled	6.5	7.2		mA
		V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 20 MHz, f_{BUS} = 20 MHz, all peripherals disabled	4.0	4.5	—	mA
		V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 10 MHz, f_{BUS} = 10 MHz, all peripherals enabled	3.5	3.9	_	mA
		V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 10 MHz, f_{BUS} = 10 MHz, all peripherals disabled	2.25	2.50	—	mA
		V_{DD} = 5.0 V, HSI off, LSI on, f_{CPU} = 32 kHz, f_{BUS} = 32 kHz, all peripherals enabled	32	41	—	μA
		V_{DD} = 5.0 V, HSI off, LSI on, f_{CPU} = 32 kHz, f_{BUS} = 32 kHz, all peripherals disabled	28	37	—	μA
I _{DD}	Supply Current	V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 0 MHz, f_{BUS} = 20 MHz, all peripherals enabled	3.5	3.9		mA
		V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 0 MHz, f_{BUS} = 20 MHz, all peripherals disabled	0.80	0.92		mA
	(Sleep Mode)	V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 0 MHz, f_{BUS} = 10 MHz, all peripherals enabled	2.20	2.25		mA
		V_{DD} = 5.0 V, HSI = 20 MHz, f_{CPU} = 0 MHz, f_{BUS} = 10 MHz, all peripherals disabled	0.65	0.75	—	mA
-	Supply current (Deep-Sleep1 Mode)	V_{DD} = 5.0 V, all clock off (HSE/HSI/LSE), LDO in low power mode, LSI on, RTC on		23	_	μA
	Supply current (Deep-Sleep2 Mode)	V_{DD} = 5.0 V, all clock off (HSE/HSI/LSE), LDO off (DMOS on), LSI on, RTC on		6.5	—	μA

Table 8. Power Consumption Characteristics

Note: 1. HSE means high speed external oscillator while HSI means 20 MHz high speed internal oscillator.

2. LSE means 32.768 kHz low speed external oscillator while LSI means 32 kHz low speed internal oscillator.

- 3. RTC means the real time clock.
- 4. Code = while (1) { 208 NOP } executed in Flash.
- 5. f_{BUS} means f_{HCLK} and $f_{\text{PCLK.}}$



Reset and Supply Monitor Characteristics

Table 9. V_{DD} Power Reset Characteristics

	$T_A = 25$ °C, unless otherwise specified.							
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit		
V _{POR}	Power On Reset Threshold (Rising Voltage on V_{DD})	T _A = -40 °C ~ 85 °C	2.22	2.35	2.48	V		
V _{PDR}	Power Down Reset Threshold (Falling Voltage on V _{DD})		2.12	2.2	2.33	V		
V _{PORHYST}	POR Hysteresis	—	—	150		mV		
t _{POR}	Reset Delay Time	V _{DD} = 5.0 V	—	0.1	0.2	ms		

Note: 1. Data based on characterization results only, not tested in production.

2. Guaranteed by design, not tested in production.

3. If the LDO is turned on, the V_{DD} POR has to be in the de-assertion condition. When the V_{DD} POR is in the assertion state then the LDO will be turned off.

Table 10. LVD/BOD Characteristics

 $T_A = 25 \text{ °C}$, unless otherwise specified.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit
V _{BOD}	Voltage of Brown Out Detection	$T_A = -40 \ ^\circ C \sim 85 \ ^\circ C$ After factory-trimmed, V_{DD} Falling edge		2.37	2.45	2.53	V
			LVDS = 000	2.57	2.65	2.73	V
			LVDS = 001	2.77	2.85	2.93	V
			LVDS = 010	2.97	3.05	3.13	V
V_{LVD}	Voltage of Low Voltage	$T_A = -40 \degree C \sim 85 \degree C,$ V_{DD} Falling edge	LVDS = 011	3.17	3.25	3.33	V
	Detection		LVDS = 100	3.37	3.45	3,53	V
			LVDS = 101	4.15	4.25	4.35	V
			LVDS = 110	4.35	4.45	4.55	V
			LVDS = 111	4.55	4.65	4.75	V
VLVDHTST	LVD Hysteresis	V _{DD} = 5.0 V	_	—	100		mV
t _{suLVD}	LVD Setup Time	V _{DD} = 5.0 V	_			5	μs
t _{atLVD}	LVD Active Delay Time	V _{DD} = 5.0 V	_				ms
I _{DDLVD}	Operation Current ⁽³⁾	V _{DD} = 5.0 V	_		10	20	μA

Note: 1. Data based on characterization results only, not tested in production.

2. Guaranteed by design, not tested in production.

3. Bandgap current is not included.

4. LVDS field is in the PWRCU LVDCSR register.



External Clock Characteristics

Table 11. High Speed External Clock (HSE) Characteristics

		T _A = 25 °C,	unless	otherv	vise spe	ecified.
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{DD}	Operation Range	T _A = -40 °C ~ 85 °C	2.5	—	5.5	V
f _{HSE}	High Speed External Oscillator Frequency (HSE)	V _{DD} = 2.5 V ~ 5.0 V	4	_	20	MHz
C_{LHSE}	Load Capacitance	V _{DD} = 5.0 V, R _{ESR} = 100 Ω @ 20 MHz	_	_	12	pF
R _{FHSE}	Internal Feedback Resistor between XTALIN and XTALOUT pins	V _{DD} = 5.0 V		0.5		MΩ
R _{ESR}	Equivalent Series Resistance	V _{DD} = 5.0 V, C _L = 12 pF @ 20 MHz, HSEDR = 0		_	110	0
NESR	Equivalent Series Resistance	V _{DD} = 2.5 V, C _L = 12 pF @ 20 MHz, HSEDR = 1			110	12
D _{HSE}	HSE Oscillator Duty Cycle	—	40	—	60	%
1	HSE Oscillator Current	$V_{DD} = 5.0 \text{ V}, \text{ R}_{ESR} = 100 \Omega,$ $C_L = 12 \text{ pF } @ 8 \text{ MHz},$ HSEDR = 0		0.85		mA
I _{DDHSE}	Consumption	V_{DD} = 5.0 V, R _{ESR} = 25 Ω, C _L = 12 pF @ 20 MHz, HSEDR = 1	— 3.0		mA	
IPWDHSE	HSE Oscillator Power Down Current	V _{DD} = 5.0 V	_	_	0.01	μA
t _{suhse}	HSE Oscillator Startup Time	V _{DD} = 5.0 V	—	—	4	ms

Note: The following guidelines are recommended to increase the stability of the crystal circuit of the HSE clock in the PCB layout:

- 1. The crystal oscillator should be located as close as possible to the MCU to keep the trace lengths as short as possible to reduce any parasitic capacitance.
- 2. Shield lines in the vicinity of the crystal by using a ground plane to isolate signals and reduce noise.
- 3. Keep any high frequency signal lines away from the crystal area to prevent any crosstalk adverse effects.



			5 °C, un	less othe	rwise sp	pecified.
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DD}	Operation Range	T _A = -40 °C ~ 85 °C	2.5	_	5.5	V
f_{CK_LSE}	LSE Frequency	V _{DD} = 2.5 V ~ 5.5 V		32.768	_	kHz
R _F	Internal Feedback Resistor	_		10		MΩ
R _{ESR}	Equivalent Series Resistance	V _{DD} = 5.0 V	30	_	TBD	kΩ
C∟	Recommended Load Capacitances	V _{DD} = 5.0 V	6	_	TBD	pF
	Oscillator Supply Current (High current mode)	$ \begin{split} f_{CK_LSE} &= 32.768 \text{ kHz}, \\ R_{ESR} &= 50 \text{ k}\Omega, C_L \geq 7 \text{ pF} \\ V_{DD} &= 2.5 \text{ V} \sim 5.5 \text{ V} \\ T_A &= -40 ^\circ\text{C} \sim +85 ^\circ\text{C} \end{split} $	_	4.0	5.6	μΑ
I _{DDLSE}	Oscillator Supply Current (Low Current Mode)	$ \begin{split} f_{CK_LSE} &= 32.768 \text{ kHz}, \\ R_{ESR} &= 50 \text{ k}\Omega, C_L < 7 \text{ pF} \\ V_{DD} &= 2.5 \text{ V} \sim 5.5 \text{ V} \\ T_A &= -40 ^\circ\text{C} \sim +85 ^\circ\text{C} \end{split} $	_	3.6	4.5	μA
	Power Down Current	—	—	—	0.01	μA
t _{sulse}	Startup Time (Low Current Mode)	f _{CK_LSI} = 32.768 kHz, V _{DD} = 2.5 V ~ 5.5 V	500	_	_	ms

Table 12. Low Speed External Clock (LSE) Characteristics

Internal Clock Characteristics

Table 13. High Speed Internal Clock (HSI) Characteristics

	$T_A = 25 \text{ °C}$, unless otherwise specified.								
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit			
V_{DD}	Operation Range	T _A = -40 °C ~ 85 °C	2.5	—	5.5	V			
f _{HSI}	HSI Frequency	V _{DD} = 5 V @ 25 °C	—	20	—	MHz			
ACC _{HSI} (Factory Calibrated HSI	V _{DD} = 5.0 V, T _A = 25 °C	-2	—	2	%			
	Oscillator Frequency Accuracy	V _{DD} = 2.5 V ~ 5.5 V T _A = -40 °C ~ 85 °C	-3	_	3	%			
Duty	Duty Cycle	f _{HSI} = 20 MHz	35	—	65	%			
1	Oscillator Supply Current	f _{HSI} = 20 MHz @	—	—	140	μA			
DDHSI	Power Down Current	V _{DD} = 2.5 V ~ 5.5 V	—		0.01	μA			
T _{SUHSI}	HSI Oscillator Startup time	f _{HSI} = 20 MHz	—	—	20	μs			

Table 14. Low Speed Internal Clock (LSI) Characteristics

		T_A = 25 °C, unless otherwise specified						
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit		
V _{DD}	Operation Range	T _A = -40 °C ~ 85 °C	2.5		5.5	V		
f _{LSI}	Low Speed Internal Oscillator Frequency (LSI)	V _{DD} = 5.0 V, T _A = -40 °C ~ 85 °C	21	32	43	kHz		
ACC _{LSI}	LSI Frequency Accuracy	$V_{DD} = 5.0 V$, with factory-trimmed	-10	_	+10	%		
IDDLSI	LSI Oscillator Operating Current	V _{DD} = 5.0 V	—	0.5	0.8	μA		
t _{SULSI}	LSI Oscillator Startup Time	V _{DD} = 5.0 V	—	—	100	μs		



Memory Characteristics

Table 15. Flash Memory Characteristics

	2	T_A = 25 °C, unless otherwise specified					
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
N _{ENDU}	Number of Guaranteed Program/Erase Cycles before failure (Endurance)	T _A = -40 °C ~ 85 °C	10	_	_	K cycles	
t _{RET}	Data Retention Time	T _A = -40 °C ~ 85 °C	10	—	—	Years	
t _{PROG}	Word Programming Time	T _A = -40 °C ~ 85 °C	20	_		μs	
t _{ERASE}	Page Erase Time	T _A = -40 °C ~ 85 °C	2	_		ms	
t _{MERASE}	Mass Erase Time	T _A = -40 °C ~ 85 °C	10	—		ms	

I/O Port Characteristics

Table 16. I/O Port Characteristics

Symbol	Doromotor	Conditions Min. Typ. Max						
Symbol	Parameter		Conditions		Typ.		Unit	
IIL.	Low Level Input Current	5.0 V I/O	$V_1 = V_{SS}$, On-chip pull-up		_	3	μA	
•12	Low Lover input ourient	Reset pin	resister disabled			3	μA	
Iн	High Level Input Current	5.0 V I/O	$V_{I} = V_{DD,}$ On-chip		—	3	μA	
ЧH	riigh Level input Guitent	Reset pin	pull-down resister disabled	—	—	3	μA	
M	Low Level Input Voltage	5.0 V I/O		-0.5	—	V _{DD} × 0.35	V	
VIL	Low Level input voltage	Reset pin		-0.5	—	V _{DD} × 0.35	V	
V	High Lovel Input Veltage	5.0 V I/O		V _{DD} × 0.65	_	V _{DD} + 0.5	V	
V _{IH} High Level Input Voltage		Reset pin		V _{DD} × 0.65		V _{DD} + 0.5	V	
	Schmitt Trigger Input	5.0 V I/O		_	0.12 × V _{DD}		mV	
V _{HYS}	Voltage Hysteresis	Reset pin		_	0.12 × V _{DD}		mV	
		5.0 V I/O 4	4 mA drive, V _{oL} = 0.6 V	4	_	—	mA	
	Low Level Output	5.0 V I/O 8	3 mA drive, V_{OL} = 0.6 V	8	_	_	mA	
I _{OL}	Current (GPIO Sink Current)	5.0 V I/O	12 mA drive, V _{OL} = 0.6 V	12	_	_	mA	
	(,	5.0 V I/O	16 mA drive, V _{oL} = 0.6 V	16	_	_	mA	
		5.0 V I/O 4 V _{OH} = V _{DD}	4 mA drive, - 0.6 V	_	4		mA	
1	High Level Output	5.0 V I/O 8 V _{OH} = V _{DD}	3 mA drive, - 0.6 V	_	8		mA	
I _{он}	Current (GPIO Source Current)	5.0 V I/O V _{OH} = V _{DD}	12 mA drive, - 0.6 V	_	12		mA	
		5.0 V I/O V _{OH} = V _{DD}	16 mA drive, - 0.6 V		16	_	mA	

 T_{A} = 25 °C, unless otherwise specified.



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
		5.0 V 4 mA drive I/O, I _{OL} = 4 mA	_	_	0.6	V
V	Low Level Output Voltage	5.0 V 8 mA drive I/O, I _{OL} = 8 mA	—	—	0.6	V
V _{OL}		5.0 V 12 mA drive I/O, I_{OL} = 12 mA	—	—	0.6	V
		5.0 V 16 mA drive I/O, I_{OL} = 16 mA	—	—	0.6	V
	High Level Output Voltage	5.0 V 4 mA drive I/O, I_{OH} = 4 mA	V _{DD} - 0.6		_	V
		5.0 V 8 mA drive I/O, I _{OH} = 8 mA	V _{DD} - 0.6	_	_	V
V _{он}		5.0 V 12 mA drive I/O, I _{OH} = 12 mA	V _{DD} - 0.6	_	_	V
		5.0 V 16 mA drive I/O, I _{OH} = 16 mA	V _{DD} - 0.6		_	V
D	Internal Dull un Desister	V _{DD} = 5.0 V	—	50	—	kΩ
R _{PU}	Internal Pull-up Resistor	V _{DD} = 3.3 V	—	76	—	kΩ
R _{PD}	Internal Pull-down	V _{DD} = 5.0 V	_	50	_	kΩ
INPD	Resistor	V _{DD} = 3.3 V	—	76	_	kΩ

12-Bit ADC Characteristics

Table 17. 12-Bit ADC Characteristics

	12-Dit ADC Characteristics	T _A = 25 °	C, unle	ss othe	rwise s	pecified.
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{DDA}	Operating Voltage	_	2.5	5.0	5.5	V
VADCIN	A/D Converter Input Voltage Range		0		V_{REF^+}	V
V_{REF^+}	A/D Converter Reference Voltage			V _{DDA}	V _{DDA}	V
I _{ADC}	Current Consumption	V _{DDA} = 5.0 V		1.4	1.5	mA
I _{ADC_DN}	Power Down Current Consumption	V _{DDA} = 5.0 V	_	_	0.1	μA
f _{ADC}	A/D Converter Clock Frequency	_	0.7	_	16	MHz
fs	Sampling Rate	_	0.05	_	1	MHz
t _{DL}	Data Latency	_	_	12.5	_	1/f _{ADC} Cycles
t _{s&H}	Sampling & Hold Time	_		3.5	_	1/f _{ADC} Cycles
t _{ADCCONV}	A/D Converter Conversion Time			16	_	1/f _{ADC} Cycles
Rı	Input Sampling Switch Resistance	_		_	1	kΩ
Cı	Input Sampling Capacitance	No pin/pad capacitance included		4	_	pF
t _{su}	Start Up Time	_		_	1	μs
Ν	Resolution	_		12	—	bits



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
INL	Integral Non-linearity Error	f_{s} = 750 kHz, V_{DDA} = 5.0 V	—	±2	±5	LSB
DNL	Differential Non-linearity Error	f_{s} = 750 kHz, V_{DDA} = 5.0 V		±1	—	LSB
Eo	Offset Error	—			±10	LSB
E _G	Gain Error	_			±10	LSB

Note: 1. Guaranteed by design, not tested in production.

- 2. Due to the A/D Converter input channel and GPIO pin-shared function design limitation, the V_{DDA} supply power of the A/D Converter has to be equal to the V_{DD} supply power of the MCU in the application circuit.
- 3. The figure below shows the equivalent circuit of the A/D Converter Sample-and-Hold input stage where C_I is the storage capacitor, R_I is the resistance of the sampling switch and R_S is the output impedance of the signal source V_S. Normally the sampling phase duration is approximately, $3.5/f_{ADC}$. The capacitance, C_I, must be charged within this time frame and it must be ensured that the voltage at its terminals becomes sufficiently close to V_S for accuracy. To guarantee this, R_S is not allowed to have an arbitrarily large value.

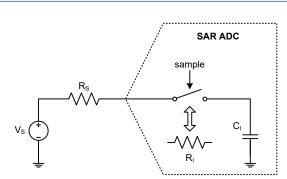


Figure 6. ADC Sampling Network Model

The worst case occurs when the extremities of the input range (0 V and V_{REF}) are sampled consecutively. In this situation a sampling error below 1/4 LSB is ensured by using the following equation:

$$R_{s} < \frac{3.5}{f_{ADC}C_{I}ln(2^{N+2})} - R_{I}$$

Where f_{ADC} is the ADC clock frequency and N is the ADC resolution (N = 12 in this case). A safe margin should be considered due to the pin/pad parasitic capacitances, which are not accounted for in this simple model.

If, in a system where the A/D Converter is used, there are no rail-to-rail input voltage variations between consecutive sampling phases, R_s may be larger than the value indicated by the equation above.



24-Bit ADC Characteristics

Table 18. 24-Bit ADC Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
AV _{DD}	Supply Voltage for VCM, ADC, PGA	_	2.4	_	5.5	V
Vout_vcm	VCM Output Voltage (VCM Pin)	AV _{DD} = 3.3 V, No load	-5%	1.25	+5%	V
TC _{VCM}	VCM Temperature Coefficient	Ta = -40 °C ~ 85 °C, AV _{DD} = 3.3V, I _{LOAD} = 10 μA		_	0.24	mV/ °C
$\Delta V_{\text{LINE}_{\text{VCM}}}$	VCM Line Regulation	$2.4 \text{ V} \le \text{AV}_{\text{DD}} \le 3.3 \text{ V}$, No load	—	—	0.4	%/V
t _{VCMS}	VCM Turn-on Stable Time	AV_{DD} = 3.3V, No load	—	—	10	ms
I _{OH}	Source Current for VCM Pin	$AV_{DD} = 3.3V, \Delta V_{OUT_VCM} = -2\%$	3	—	—	mA
I _{OL}	Sink Current for VCM Pin	$AV_{DD} = 3.3V, \Delta V_{OUT_VCM} = +2\%$	3	—	_	mA
ADC & A	DC Internal Reference Vol	tage (Sigma Delta ADC)				
		VCM enable, VRBUFP = 1 and VRBUFN = 1			1120	μA
I _{ADC}	Additional Current for ADC Enable	VCM enable, VRBUFP = 0 and VRBUFN = 0		820	970	μA
		VCM disable, VRBUFP = 0 and VRBUFN = 0		500	650	μA
I _{ADSTB}	Standby Current	ADC power down, no load	—	—	1	μA
RS _{ADC}	Resolution		_	_	24	bit
INL	Integral Non-linearity	AV_{DD} = 3.3 V, V_{REF} = 1.25 V, Δ SI = ±450 mV, PGA Gain = 1		±50	_	ppm
		V _{REF} = 2.5 V, Gain = 32 Data rate = 10 Hz		18.0	_	Bit
NFB	Noise Free BitsVREF = 2.5 V, Gain = 64Data rate = 10 Hz			17.4	_	Bit
		V _{REF} = 2.5 V, Gain = 128 Data rate = 10 Hz		16.7	—	Bit
		V _{REF} = 2.5 V, Gain = 32 Data rate = 10 Hz		20.7	—	Bit
ENOB	Effective Number of Bits	V _{REF} = 2.5 V, Gain = 64 Data rate = 10 Hz		20.1	_	Bit
		V _{REF} = 2.5 V, Gain = 128 Data rate = 10 Hz		19.4	—	Bit
f _{ADCK}	ADC Clock Frequency	_	40	409.6	440	kHz
func	ADC Output Data Rate	f _{MCLK} = 4.9152 MHz, FLMS[2:0] = 000B	5		640	Hz
f _{ADO}		f _{MCLK} = 4.9152 MHz, FLMS[2:0] = 010B	12.5	_	1600	Hz
V _{REFP}		VREFS = 1, VRBUFP = 0,	V _{REFN} + 1	_	AV_{DD}	V
V _{REFN}	External Reference Input Voltage	VRBUFN = 0	0	_	V _{REFP} - 1	V
V _{REF}		$V_{REF} = (V_{REFP} - V_{REFN}) \times VREFGN$	1		$AV_{DD}/2$	V



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
PGA							
$V_{\text{CM}_{\text{PGA}}}$	Common Mode Voltage Range	_	0.4		AV _{DD} - 0.95	V	
ΔD_1	Differentail Input Voltage Range	Gain = PGAGN × ADGN, $\Delta D_1 = DI+ - DI-$	-V _{REF} / Gain	_	+V _{REF} / Gain	V	
Tempera	iture Sensor						
TC _{TS}	Temperature Sensor Temperature Coefficient	$\label{eq:transform} \begin{array}{l} {\rm Ta} = -40^{\circ}{\rm C} \sim 85^{\circ}{\rm C}, {\rm V}_{\rm REF} = 1.25{\rm V}, \\ {\rm VGS}[1:0] = 00{\rm B} \; ({\rm Gain} = 1), \\ {\rm VRBUFP} = 0, {\rm VRBUFN} = 0 \end{array}$		175		μV/ °C	

Effective Number of Bits (ENOB)

						Vre	_{EF} =2.5V, f _{AD}	_{ск} =163kHz
Data Rate				PGA	Gain			
(SPS)	1	2	4	8	16	32	64	128
5	21.5	21.2	21.1	21.1	21.0	20.9	20.4	19.6
10	21.2	21.0	21.0	20.9	20.8	20.7	20.1	19.4
20	21.1	20.7	20.7	20.6	20.5	20.3	19.7	18.9
40	20.6	20.5	20.4	20.2	20.1	19.9	19.2	18.5
80	20.2	20.1	20.0	19.9	19.8	19.5	18.8	18.0
160	19.7	19.5	19.5	19.4	19.3	19.0	18.4	17.6
320	19.1	18.9	18.9	18.8	18.7	18.5	17.9	17.1
640	18.6	18.4	18.4	18.3	18.3	18.0	17.4	16.6

V_{REF} =2.5V, f_{ADCK} =409kHz

Data Rate	PGA Gain								
(SPS)	1	2	4	8	16	32	64	128	
12.5	21.9	21.4	21.4	21.3	21.1	20.7	19.9	19.2	
25	21.6	21.1	21.1	21.0	20.9	20.4	19.6	18.8	
50	21.2	20.9	20.8	20.7	20.4	19.9	19.2	18.3	
100	20.8	20.5	20.4	20.3	20.0	19.5	18.8	17.9	
200	20.3	19.7	19.7	19.6	19.4	18.9	18.2	17.4	
400	19.3	19.0	19.0	18.9	18.8	18.4	17.8	16.9	
800	18.8	18.6	18.6	18.5	18.3	17.9	17.2	16.5	
1600	18.4	18.2	18.2	18.1	17.9	17.4	16.8	16.1	



$V_{\text{REF}}\text{=}1.65\text{V}\text{, }f_{\text{ADCK}}\text{=}163\text{kHz}$

Data Rate	PGA Gain								
(SPS)	1	2	4	8	16	32	64	128	
5	21.5	21.2	21.2	21.1	20.9	20.5	20.0	19.2	
10	21.3	21.0	20.9	20.7	20.5	20.2	19.5	18.7	
20	20.9	20.6	20.5	20.4	20.2	19.8	19.1	18.3	
40	20.4	20.1	20.1	20.0	19.8	19.4	18.8	18.0	
80	19.8	19.5	19.5	19.4	19.2	18.8	18.2	17.5	
160	19.3	19.0	19.0	18.9	18.7	18.4	17.8	17.0	
320	18.8	18.5	18.5	18.4	18.3	17.9	17.3	16.5	
640	18.3	18.1	18.1	18.0	17.8	17.5	16.8	16.0	

 V_{REF} =1.65V, f_{ADCK} =409kHz

Data Rate	PGA Gain								
(SPS)	1	2	4	8	16	32	64	128	
12.5	21.8	21.4	21.2	21.1	20.7	20.3	19.5	18.6	
25	21.4	21.1	20.9	20.7	20.3	19.7	19.0	18.2	
50	20.9	20.6	20.5	20.3	19.9	19.4	18.6	17.7	
100	20.4	20.2	20.0	19.8	19.4	18.9	18.1	17.3	
200	19.8	19.4	19.3	19.2	18.9	18.4	17.7	16.8	
400	19.0	18.8	18.7	18.6	18.4	17.8	17.2	16.3	
800	18.7	18.4	18.3	18.2	17.9	17.4	16.7	15.8	
1600	18.2	18.0	17.9	17.7	17.3	16.7	16.2	15.4	

 $V_{\text{REF}}\text{=}1.2\text{V}\text{, }f_{\text{ADCK}}\text{=}163\text{kHz}$

Data Rate	PGA Gain								
(SPS)	1	2	4	8	16	32	64	128	
5	20.6	20.4	20.4	20.3	20.3	20.1	19.6	18.9	
10	20.5	20.3	20.3	20.2	20.0	19.9	19.2	18.4	
20	20.3	19.9	19.9	19.8	19.7	19.4	18.8	18.0	
40	19.8	19.5	19.5	19.4	19.2	18.9	18.3	17.5	
80	19.3	19.1	19.1	19.0	18.8	18.5	17.8	17.0	
160	19.0	18.8	18.7	18.6	18.3	18.0	17.4	16.5	
320	18.5	18.2	18.2	18.1	17.8	17.5	16.9	16.1	
640	17.9	17.7	17.7	17.6	17.3	17.0	16.4	15.6	



V_{REF}=1.2V, f_{ADCK}=409kHz

Data Rate	PGA Gain								
(SPS)	1	2	4	8	16	32	64	128	
12.5	20.9	20.7	20.5	20.3	20.1	19.8	19.1	18.2	
25	20.7	20.4	20.2	20.1	19.8	19.4	18.6	17.8	
50	20.3	20.1	19.8	19.7	19.4	18.8	18.1	17.4	
100	19.9	19.6	19.4	19.2	18.9	18.4	17.7	16.8	
200	19.5	19.2	19.0	18.8	18.5	17.9	17.2	16.4	
400	18.9	18.7	18.6	18.4	18.0	17.5	16.7	15.9	
800	18.5	18.2	18.0	17.8	17.5	16.9	16.2	15.4	
1600	17.9	17.6	17.5	17.3	16.9	16.4	15.7	14.9	

MCTM/GPTM/PWM Characteristics

Table 19. MCTM/GPTM/PWM Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
f _{TM}	Timer Clock Source for MCTM, GPTM and PWM	—	—	_	f _{PCLK}	MHz
t _{RES}	Timer Resolution Time	—	1		_	f _{тм}
f _{EXT}	External Single Frequency on Channel 1 ~ 4	—	—	_	1/2	f™
RES	Timer Resolution	—			16	bits

I²C Characteristics

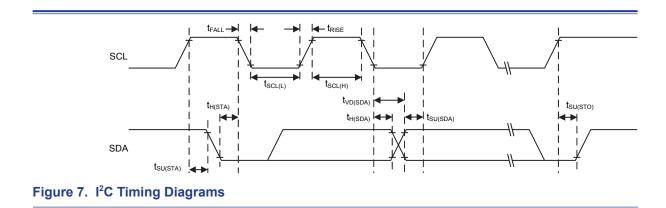
Table 20. I²C Characteristics

Symbol	Parameter	Standar	d Mode	Fast	Mode	Fast Plu	ıs Mode	Unit
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
f _{SCL}	SCL Clock Frequency	—	100	_	400		1000	kHz
$t_{\rm SCL(H)}$	SCL Clock High Time	4.5	—	1.125	—	0.45	—	μs
t _{SCL(L)}	SCL Clock Low Time	4.5	—	1.125	_	0.45	—	μs
t _{FALL}	SCL And SDA Fall Time	—	1.3	_	0.34	_	0.135	μs
t _{RISE}	SCL And SDA Rise Time	_	1.3	_	0.34		0.135	μs
$t_{\rm SU(SDA)}$	SDA Data Setup Time	500	_	125		50	_	ns
+	SDA Data Hold Time (Note 5)	0	_	0		0	_	ns
$t_{H(SDA)}$	SDA Data Hold Time (Note 6)	100	—	100		100	_	ns
$t_{VD(SDA)}$	SDA Data Valid Time		1.6	_	0.475		0.25	μs
$t_{\rm SU(STA)}$	START Condition Setup Time	500		125		50		ns
t _{H(STA)}	START Condition Hold Time	0		0		0	_	ns
$t_{\text{SU(STO)}}$	STOP Condition Setup Time	500	—	125	—	50		ns

Note: 1. Guaranteed by design, not tested in production.

- 2. To achieve 100 kHz standard mode, the peripheral clock frequency must be higher than 2 MHz.
- 3. To achieve 400 kHz fast mode, the peripheral clock frequency must be higher than 8 MHz.
- 4. To achieve 1 MHz fast mode plus, the peripheral clock frequency must be higher than 20 MHz.
- 5. The above characteristic parameters of the I^2C bus timing are based on: COMB_FILTER_En = 0 and SEQ_FILTER = 00.
- 6. The above characteristic parameters of the I²C bus timing are based on: COMB_FILTER_En = 1 and SEQ_FILTER = 00.





SPI Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SPI Mast	er Mode			1	I	1
f _{scк}	SPI Master Output SCK Clock Frequency	Master mode SPI peripheral clock frequency f _{PCLK}	_		f _{PCLK} /2	MHz
t _{scк(н)} t _{scк(L)}	SCK Clock High and Low Time	_	t _{sск} /2 - 2	_	t _{sск} /2 + 1	ns
t _{V(MO)}	Data Output Valid Time			—	5	ns
t _{H(MO)}	Data Output Hold Time		2	—		ns
t _{SU(MI)}	Data Input Setup Time		5	—		ns
t _{H(MI)}	Data Input Hold Time	_	5			ns
SPI Slave	Mode					
f _{scк}	SPI Slave Input SCK Clock Frequency	Slave mode SPI peripheral clock frequency f _{PCLK}			f _{PCLK} /З	MHz
Duty _{sck}	SPI Slave Input SCK Clock Duty Cycle	_	30		70	%
$t_{\rm SU(SEL)}$	SEL Enable Setup Time	_	3 t _{PCLK}	—		ns
t _{H(SEL)}	SEL Enable Hold Time	_	2 t _{PCLK}			ns
t _{A(SO)}	Data Output Access Time	_	—	—	3 t _{PCLK}	ns
$t_{\text{DIS}(\text{SO})}$	Data Output Disable Time	_	—	—	10	ns
t _{V(SO)}	Data Output Valid Time	_			25	ns
t _{H(SO)}	Data Output Hold Time		15	—		ns
t _{SU(SI)}	Data Input Setup Time		5	—		ns
t _{H(SI)}	Data Input Hold Time	_	4	_	_	ns

2. f_{PCLK} is SPI peripheral clock frequency and $t_{PCLK} = 1/f_{PCLK}$.

6



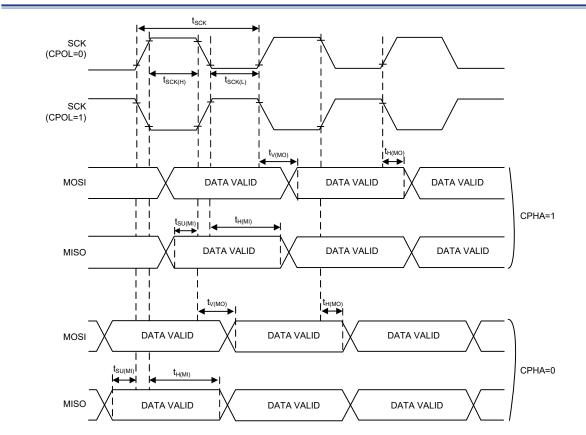
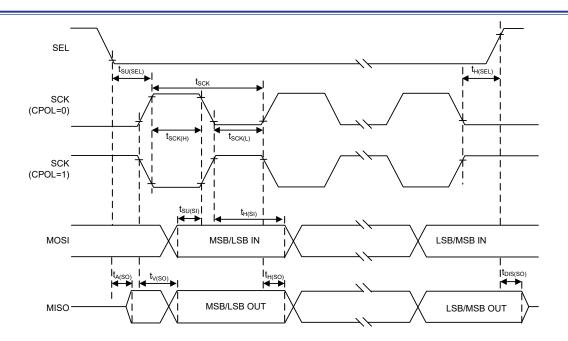


Figure 8. SPI Timing Diagrams – SPI Master Mode







7 Package Information

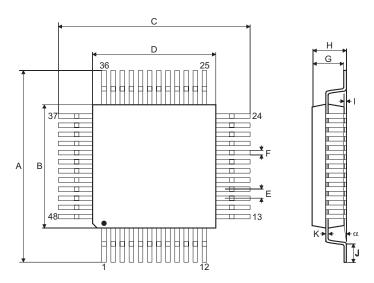
Note that the package information provided here is for consultation purposes only. As this information may be updated at regular intervals users are reminded to consult

Additional supplementary information with regard to packaging is listed below. Click on the relevant section to be transferred to the relevant website page.

- Package Information (include Outline Dimensions, Product Tape and Reel Specifications)
- The Operation Instruction of Packing Materials
- Carton information



48-pin LQFP (7mm × 7mm) Outline Dimensions



Symbol		Dimensions in inch	
Symbol	Min.	Nom.	Max.
А	_	0.354 BSC	—
В	—	0.276 BSC	—
С	—	0.354 BSC	—
D	—	0.276 BSC	—
E	—	0.020 BSC	—
F	0.007	0.009	0.011
G	0.053	0.055	0.057
Н	—	—	0.063
I	0.002	—	0.006
J	0.018	0.024	0.030
К	0.004	—	0.008
α	0°	_	7°

Symbol	Dimensions in mm		
	Min.	Nom.	Max.
А	_	9.0 BSC	_
В	—	7.0 BSC	—
С	—	9.0 BSC	—
D	—	7.0 BSC	—
E	—	0.5 BSC	—
F	0.17	0.22	0.27
G	1.35	1.4	1.45
Н	—	—	1.60
I	0.05	—	0.15
J	0.45	0.60	0.75
K	0.09		0.20
α	0°	—	7°



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